

# mos integrated circuit $\mu$ PD78F0034A, 78F0034AY

### 8-BIT SINGLE-CHIP MICROCONTROLLER

#### **DESCRIPTION**

The  $\mu$ PD78F0034A is a member of the  $\mu$ PD780034A Subseries in the 78K/0 Series, and is equivalent to the  $\mu$ PD780034A but with flash memory in place of internal ROM.

The  $\mu$ PD78F0034AY is a member of the  $\mu$ PD780034AY Subseries, featuring flash memory in place of the internal ROM of the  $\mu$ PD780034AY.

The  $\mu$ PD78F0034A incorporates flash memory, which can be programmed and erased while mounted on the board.

Detailed function descriptions are provided in the following user's manuals. Be sure to read them before designing.

 $\mu$ PD780024A, 780034A, 780024AY, 780034AY Subseries User's Manual: U14046E 78K/0 Series Instruction User's Manual: U12326E

#### **FEATURES**

Pin-compatible with mask ROM versions (except VPP pin)

Flash memory: 32 KB<sup>Note</sup>
 Internal high-speed RAM: 1,024 bytes<sup>Note</sup>
 Supply voltage: VDD = 1.8 to 5.5 V

**Note** The flash memory and internal high-speed RAM capacities can be changed with the memory size switching register (IMS).

**Remark** For the differences between the flash memory and the mask ROM versions, refer to **4. DIFFERENCES BETWEEN**  $\mu$ **PD78F0034A, 78F0034AY, AND MASK ROM VERSIONS**.

#### ★ ORDERING INFORMATION

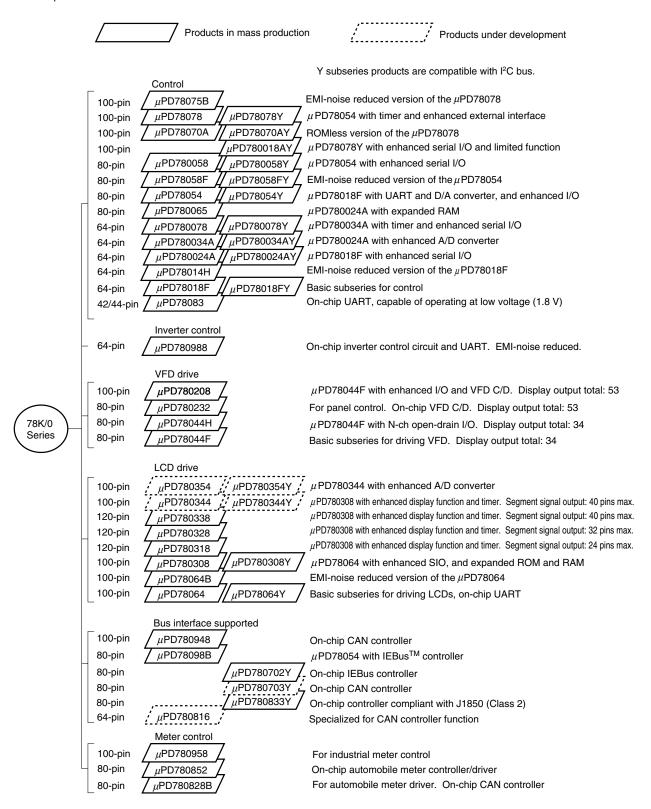
Part Number	Package	Internal ROM
$\mu$ PD78F0034ACW	64-pin plastic SDIP (19.05 mm (750))	Flash memory
$\mu$ PD78F0034AGB-8EU	64-pin plastic LQFP (10 $\times$ 10)	Flash memory
$\mu$ PD78F0034AGC-8BS	64-pin plastic LQFP (14 $\times$ 14)	Flash memory
$\mu$ PD78F0034AGC-AB8	64-pin plastic QFP (14 $\times$ 14)	Flash memory
$\mu$ PD78F0034AGK-9ET	64-pin plastic TQFP (12 $\times$ 12)	Flash memory
$\mu$ PD78F0034AYCW	64-pin plastic SDIP (19.05 mm (750))	Flash memory
$\mu$ PD78F0034AYGB-8EU	64-pin plastic LQFP (10 $\times$ 10)	Flash memory
$\mu$ PD78F0034AYGC-8BS	64-pin plastic LQFP (14 × 14)	Flash memory
$\mu$ PD78F0034AYGC-AB8	64-pin plastic QFP (14 $\times$ 14)	Flash memory
$\mu$ PD78F0034AYGK-9ET	64-pin plastic TQFP (12 $\times$ 12)	Flash memory

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

#### **★** 78K/0 SERIES LINEUP

The products in the 78K/0 Series are listed below. The names enclosed in boxes are subseries names.



**Remark** VFD (Vacuum Fluorescent Display) is referred to as FIP<sup>TM</sup> (Fluorescent Indicator Panel) in some documents, but the functions of the two are the same.



The major functional differences among the subseries are listed below.

# Non-Y subseries

	Function	ROM Capacity		Tin	ner		8-Bit	10-Bit	8-Bit	Serial Interface	I/O	V <sub>DD</sub>	External
Subseries	Name	(Bytes)	8-Bit	16-Bit	Watch	WDT	A/D	A/D	D/A			Value	Expansion
Control	μPD78075B	32 K to 40 K	4 ch	1 ch	1 ch	1 ch	8 ch	_	2 ch	3 ch (UART: 1 ch)	88	1.8 V	√
	μPD78078	48 K to 60 K											
	μPD78070A	_									61	2.7 V	
	$\mu$ PD780058	24 K to 60 K	2 ch							3 ch (time-division UART: 1 ch)	68	1.8 V	
	$\mu$ PD78058F	48 K to 60 K								3 ch (UART: 1 ch)	69	2.7 V	
	μPD78054	16 K to 60 K										2.0 V	
	μPD780065	40 K to 48 K							-	4 ch (UART: 1 ch)	60	2.7 V	
	μPD780078	48 K to 60 K		2 ch			_	8 ch		3 ch (UART: 2 ch)	52	1.8 V	
	μPD780034A	8 K to 32 K		1 ch						3 ch (UART: 1 ch)	51		
	μPD780024A						8 ch	_					
	μPD78014H									2 ch	53		
	μPD78018F	8 K to 60 K											
	μPD78083	8 K to 16 K		_	_					1 ch (UART: 1 ch)	33		_
Inverter control	μPD780988	16 K to 60 K	3 ch	Note	ı	1 ch	_	8 ch	_	3 ch (UART: 2 ch)	47	4.0 V	√
VFD	μPD780208	32 K to 60 K	2 ch	1 ch	1 ch	1 ch	8 ch	_	_	2 ch	74	2.7 V	-
drive	μPD780232	16 K to 24 K	3 ch	_	_		4 ch				40	4.5 V	
	μPD78044H	32 K to 48 K	2 ch	1 ch	1 ch		8 ch			1 ch	68	2.7 V	
	μPD78044F	16 K to 40 K								2 ch			
LCD	μPD780354	24 K to 32 K	4 ch	1 ch	1 ch	1 ch	_	8 ch	_	3 ch (UART: 1 ch)	66	1.8 V	_
drive	μPD780344					·	8 ch	_					
	μPD780338	48 K to 60 K	3 ch	2 ch			_	10 ch	1 ch	2 ch (UART: 1 ch)	54		
	μPD780328										62		
	μPD780318										70		
	μPD780308	48 K to 60 K	2 ch	1 ch			8 ch	_	_	3 ch (time-division UART: 1 ch)	57	2.0 V	
	μPD78064B	32 K								2 ch (UART: 1 ch)			
	μPD78064	16 K to 32 K											
Bus	μPD780948	60 K	2 ch	2 ch	1 ch	1 ch	8 ch	_	_	3 ch (UART: 1 ch)	79	4.0 V	√
interface	μPD78098B	40 K to 60 K		1 ch					2 ch		69	2.7 V	_
supported	μPD780816	32 K to 60 K		2 ch			12 ch		_	2 ch (UART: 1 ch)	46	4.0 V	
Meter control	μPD780958	48 K to 60 K	4 ch	2 ch	_	1 ch	-	_	_	2 ch (UART: 1 ch)	69	2.2 V	_
Dash-	μPD780852	32 K to 40 K	3 ch	1 ch	1 ch	1 ch	5 ch	-	-	3 ch (UART: 1 ch)	56	4.0 V	_
board control	μPD780828B	32 K to 60 K									59		

Note 16-bit timer: 2 channels 10-bit timer: 1 channel

# Y subseries

	Function	ROM Capacity		Tin	ner		8-Bit	10-Bit	8-Bit	Serial Interface	I/O	V <sub>DD</sub>	External
Subseries	Name	(Bytes)	8-Bit	16-Bit	Watch	WDT	A/D	A/D	D/A			Value	Expansion
Control	μPD78078Y	48 K to 60 K	4 ch	1 ch	1 ch	1 ch	8 ch	_	2 ch	3 ch (UART: 1 ch, I <sup>2</sup> C: 1 ch)	88	1.8 V	<b>√</b>
	μPD78070AY	-									61	2.7 V	
	μPD780018AY	48 K to 60 K							-	3 ch (I <sup>2</sup> C: 1 ch)	88		
	μPD780058Y	24 K to 60 K	2 ch						2 ch	3 ch (time-division UART: 1 ch, I <sup>2</sup> C: 1 ch)	68	1.8 V	
	μPD78058FY	48 K to 60 K								3 ch (UART: 1 ch, I <sup>2</sup> C: 1 ch)	69	2.7 V	
	μPD78054Y	16 K to 60 K										2.0 V	
	μPD780078Y	48 K to 60 K		2 ch			_	8 ch	_	4 ch (UART: 2 ch, I <sup>2</sup> C: 1 ch)	52	1.8 V	
	μPD780034AY	8 K to 32 K		1 ch						3 ch (UART: 1 ch, I <sup>2</sup> C: 1 ch)	51		
	μPD780024AY						8 ch	_					
	μPD78018FY	8 K to 60 K								2 ch (I <sup>2</sup> C: 1 ch)	53		
LCD	μPD780354Y	24 K to 32 K	4 ch	1 ch	1 ch	1 ch	_	8 ch	_	4 ch (UART: 1 ch,	66	1.8 V	-
drive	μPD780344Y						8 ch	_		I <sup>2</sup> C: 1 ch)			
	μPD780308Y	48 K to 60 K	2 ch							3 ch (time-division UART: 1 ch, I <sup>2</sup> C: 1 ch)	57	2.0 V	
	μPD78064Y	16 K to 32 K								2 ch (UART: 1 ch, I <sup>2</sup> C: 1 ch)			
Bus	μPD780701Y	60 K	3 ch	2 ch	1 ch	1 ch	16 ch	_	_	4 ch (UART: 1 ch, I <sup>2</sup> C: 1 ch)	67	3.5 V	
	μPD780703Y												
supported	μPD780833Y										65	4.5 V	

**Remark** Functions other than the serial interface are common to both the Y and non-Y subseries.

4 Data Sheet U14040EJ4V0DS www.DataSheet4U.com



# **OVERVIEW OF FUNCTIONS**

Item	Part Number	μPD78F0034A μPD78F0034AY						
Internal	Flash memory	32 KB <sup>Note</sup>						
memory	High-speed RAM	1,024 bytes <sup>Note</sup>						
Memory space		64 KB						
General-purpose	e registers	8 bits × 32 registers (8 bits × 8 registers ×	4 banks)					
Minimum instruc	tion execution time	On-chip minimum instruction execution tim	ne cycle variable function					
	When main system clock selected	0.24 μs/0.48 μs/0.95 μs/1.91 μs/3.81 μs ( (						
	When subsystem clock selected	122 μs (@ 32.768 kHz operation)						
Instruction set		<ul> <li>16-bit operation</li> <li>Multiply/divide (8 bits × 8 bits, 16 bits ÷ 8</li> <li>Bit manipulation (set, reset, test, Boolean</li> <li>BCD adjust, etc.</li> </ul>	,					
I/O ports		Total:	51					
		CMOS input: CMOS I/O: N-ch open-drain I/O (5 V withstand voltage)	8 39 ge): 4					
A/D converter		<ul> <li>10-bit resolution × 8 channels</li> <li>Operable over a wide power supply voltage range: AV<sub>DD</sub> = 1.8 to 5.5 V</li> </ul>						
Serial interface		UART mode: 1 channel     3-wire serial I/O mode: 2 channels	UART mode:  1 channel  3-wire serial I/O mode:  1 channel  1 <sup>2</sup> C bus mode  (multimaster supporting): 1 channel					
Timers		16-bit timer/event counter: 1 channel     8-bit timer/event counter: 2 channels     Watch timer: 1 channel     Watchdog timer: 1 channel						
Timer outputs		3 (8-bit PWM output capable: 2)	•					
Clock output		65.5 kHz, 131 kHz, 262 kHz, 524 kHz, 1.05 MHz, 2.10 MHz, 4.19 MHz, 8.38 MHz     (@ 8.38 MHz operation with main system clock)     32.768 kHz (@ 32.768 kHz operation with subsystem clock)						
Buzzer output		1.02 kHz, 2.05 kHz, 4.10 kHz, 8.19 kHz (@	8.38 MHz operation with main system clock)					
Vectored interru	pt Maskable	Internal: 13, external: 5						
sources	Non-maskable	Internal: 1						
	Software	1						
Test inputs		Internal: 1, external: 1						
Supply voltage		V <sub>DD</sub> = 1.8 to 5.5 V						
Operating ambie	ent temperature	T <sub>A</sub> = -40 to +85°C						
Package		64-pin plastic SDIP (19.05 mm (750))     64-pin plastic LQFP (10 × 10)     64-pin plastic LQFP (14 × 14)     64-pin plastic QFP (14 × 14)     64-pin plastic TQFP (12 × 12)						

**Note** The capacities of the flash memory and the internal high-speed RAM can be changed with the memory size switching register (IMS).



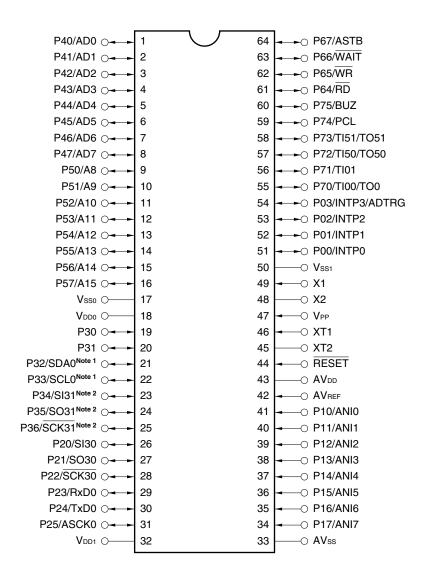
# **CONTENTS**

1.	PIN CONFIGURATION (TOP VIEW)	7
2.	BLOCK DIAGRAM	10
3.	PIN FUNCTIONS	11
	3.1 Port Pins	11
	3.2 Non-Port Pins	12
	3.3 Pin I/O Circuits and Recommended Connection of Unused Pins	14
4.	DIFFERENCES BETWEEN $\mu$ PD78F0034A, 78F0034AY, AND MASK ROM VERSIONS	17
5.	MEMORY SIZE SWITCHING REGISTER (IMS)	19
6.	FLASH MEMORY PROGRAMMING	20
	6.1 Selection of Communication Mode	20
	6.2 Flash Memory Programming Functions	22
	6.3 Connection of Flashpro III	22
7.	ELECTRICAL SPECIFICATIONS	24
8.	PACKAGE DRAWINGS	47
9.	RECOMMENDED SOLDERING CONDITIONS	52
ΑP	PPENDIX A. DEVELOPMENT TOOLS	54
ΛP	PRENDLY R. DELATED DOCUMENTS	61

www.DataSheet4U.com

### 1. PIN CONFIGURATION (TOP VIEW)

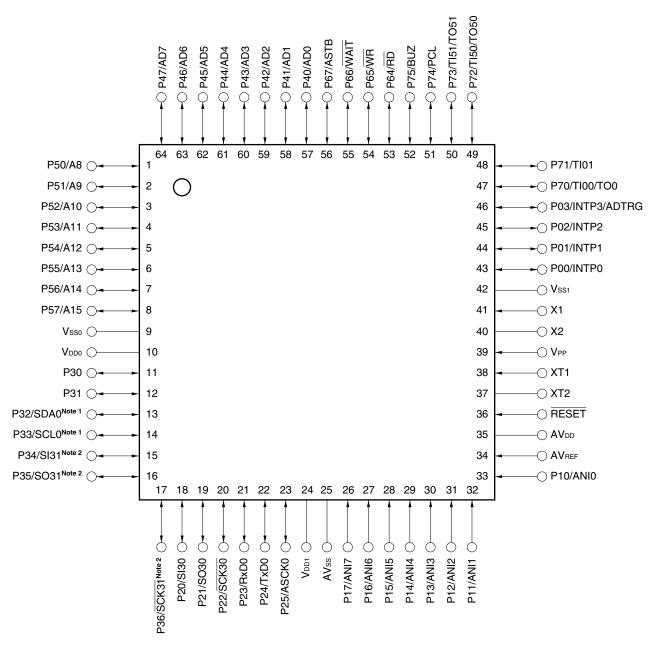
64-pin plastic SDIP (19.05 mm (750))
 μPD78F0034ACW, 78F0034AYCW



- **Notes 1.** SDA0 and SCL0 are incorporated only in the  $\mu$ PD78F0034AY Subseries.
  - **2.** SI31, SO31, and SCK31 are incorporated only in the  $\mu$ PD78F0034A Subseries.
- Cautions 1. Connect the VPP pin directly to Vsso or Vss1 in normal operation mode.
  - 2. Connect the AVss pin to Vsso.

**Remark** When the μPD78F0034A and 78F0034AY are used in application fields that require reduction of the noise generated from inside the microcontroller, the implementation of noise reduction measures, such as supplying voltage to V<sub>DD0</sub> and V<sub>DD1</sub> individually and connecting V<sub>SS0</sub> and V<sub>SS1</sub> to different ground lines, is recommended.

- 64-pin plastic LQFP ( $10 \times 10$ )  $\mu$ PD78F0034AGB-8EU, 78F0034AYGB-8EU
- 64-pin plastic LQFP (14  $\times$  14) μPD78F0034AGC-8BS, 78F0034AYGC-8BS
- 64-pin plastic QFP (14  $\times$  14)  $\mu$ PD78F0034AGC-AB8, 78F0034AYGC-AB8
- 64-pin plastic TQFP (12  $\times$  12)  $\mu$ PD78F0034AGK-9ET, 78F0034AYGK-9ET



- **Notes 1.** SDA0 and SCL0 are incorporated only in the  $\mu$ PD78F0034AY Subseries.
  - 2. SI31, SO31, and  $\overline{SCK31}$  are incorporated only in the  $\mu$ PD78F0034A Subseries.
- Cautions 1. Connect the VPP pin directly to Vsso or Vss1 in normal operation mode.
  - 2. Connect the AVss pin to Vsso.
- **Remark** When the  $\mu$ PD78F0034A and 78F0034AY are used in application fields that require reduction of the noise generated from inside the microcontroller, the implementation of noise reduction measures, such as supplying voltage to VDD0 and VDD1 individually and connecting Vss0 and Vss1 to different ground lines, is recommended.

P00 to P03:

A8 to A15: Address bus P70 to P75: Port 7

AD0 to AD7: Address/data bus PCL: Programmable clock

ADTRG: RD: Read strobe AD trigger input ANI0 to ANI7: RESET: Reset

Analog input ASCK0: Asynchronous serial clock RxD0: Receive data

ASTB: Address strobe SCK30, SCK31, SCL0: Serial clock SDA0: AV<sub>DD</sub>: Analog power supply Serial data AVREF: Analog reference voltage SI30, SI31: Serial input

AVss: Analog ground SO30, SO31: Serial output BUZ: Buzzer clock TI00, TI01, TI50, TI51: Timer input INTP0 to INTP3: External interrupt input TO0, TO50, TO51: Timer output Port 0

P10 to P17: V<sub>DD0</sub>, V<sub>DD1</sub>: Port 1 Power supply Port 2 V<sub>PP</sub>: P20 to P25: Programming power supply

TxD0:

P30 to P36: Port 3 Vsso, Vss1: Ground WAIT: P40 to P47: Port 4 Wait

WR: P50 to P57: Port 5 Write strobe

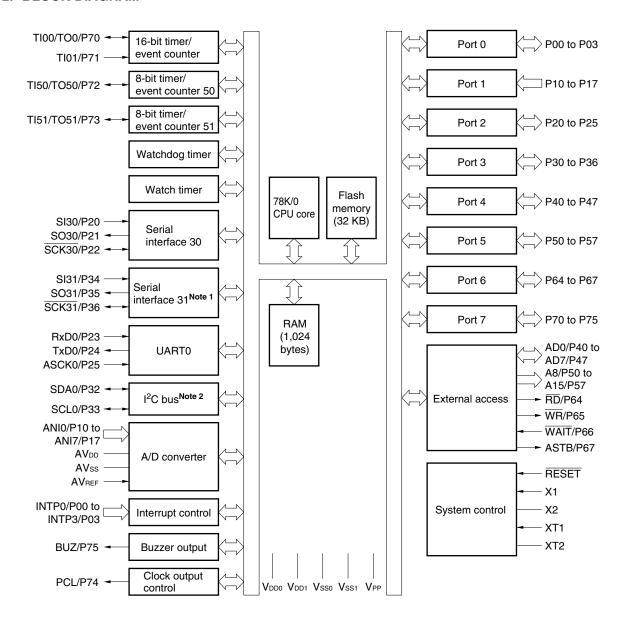
X1, X2: P64 to P67: Port 6 Crystal (main system clock)

XT1, XT2: Crystal (subsystem clock)

Transmit data

#### www.bataoncct+o.com

#### 2. BLOCK DIAGRAM



**Notes 1.** Incorporated only in the  $\mu$ PD78F0034A

2. Incorporated only in the  $\mu$ PD78F0034AY



# 3. PIN FUNCTIONS

# 3.1 Port Pins (1/2)

Pin Name	I/O		Function	After Reset	Alternate Function
P00	I/O	Port 0		Input	INTP0
P01		4-bit I/O port.		INTP1	
P02		Input/output can be specified  An on-chip pull-up resistor ca			INTP2
P03		An on-chip pull-up resistor ca	n be specified by software.		INTP3/ADTRG
P10 to P17	Input	Port 1 8-bit input-only port.		Input	ANI0 to ANI7
P20	I/O	Port 2		Input	SI30
P21		6-bit I/O port.			SO30
P22		Input/output can be specified			SCK30
P23		An on-chip pull-up resistor ca	n be specified by software.		RxD0
P24					TxD0
P25					ASCK0
P30	I/O	Port 3	N-ch open-drain I/O port.	Input	-
P31		7-bit I/O port.	LEDs can be driven directly.		
P32		Input/output can be specified			SDA0 <sup>Note 1</sup>
P33		in 1-bit units.			SCL0 <sup>Note 1</sup>
P34			An on-chip pull-up resistor can be		SI31 Note 2
P35			specified by software.		SO31 <sup>Note 2</sup>
P36					SCK31 Note 2
P40 to P47	I/O	Port 4 8-bit I/O port. Input/output can be specified An on-chip pull-up resistor ca Interrupt request flag KRIF is		Input	AD0 to AD7
P50 to P57	I/O	Port 5 8-bit I/O port. LEDs can be driven directly. Input/output can be specified An on-chip pull-up resistor ca		Input	A8 to A15
P64	I/O	Port 6		Input	RD
P65		4-bit I/O port.			WR
P66		Input/output can be specified An on-chip pull-up resistor ca			WAIT
P67		An on-only pull-up resistor ca	ii be specified by software.		ASTB

**Notes 1.** SDA0 and SCL0 are incorporated only in the  $\mu$ PD78F0034AY Subseries.

2. SI31, SO31, and  $\overline{\text{SCK31}}$  are incorporated only in the  $\mu\text{PD78F0034A}$  Subseries.

3.1 Port Pins (2/2)

Pin Name	I/O	Function	After Reset	Alternate Function
P70	I/O	Port 7	Input	TI00/TO0
P71		6-bit I/O port.		TI01
P72		Input/output can be specified in 1-bit units.  An on-chip pull-up resistor can be specified by software.		TI50/TO50
P73		All off-only pull-up resistor can be specified by software.		TI51/TO51
P74				PCL
P75				BUZ

# 3.2 Non-Port Pins (1/2)

Pin Name	I/O	Function	After Reset	Alternate Function
INTP0	Input	External interrupt request input by which the valid edge (rising edge,	Input	P00
INTP1		falling edge, or both rising and falling edges) can be specified.		P01
INTP2				P02
INTP3				P03/ADTRG
SI30	Input	Serial interface serial data input.	Input	P20
SI31 Note 1				P34
SDA0 <sup>Note 2</sup>	I/O	Serial interface serial data input/output	Input	P32
SO30	Output	Serial interface serial data output.	Input	P21
SO31 <sup>Note 1</sup>				P35
SCK30	I/O	Serial interface serial clock input/output.	Input	P22
SCK31 Note 1				P36
SCL0 <sup>Note 2</sup>				P33
RxD0	Input	Serial data input for asynchronous serial interface.	Input	P23
TxD0	Output	Serial data output for asynchronous serial interface.	Input	P24
ASCK0	Input	Serial clock input for asynchronous serial interface.	Input	P25
TI00	Input	External count clock input to 16-bit timer/event counter 0.  Capture trigger signal input to capture register 01 (CR01) of 16-bit timer/event counter 0.	Input	P70/TO0
TI01		Capture trigger signal input to capture register 00 (CR00) of 16-bit timer/ event counter 0.		P71
TI50		External count clock input to 8-bit timer/event counter 50.		P72/TO50
TI51		External count clock input to 8-bit timer/event counter 51.		P73/TO51
TO0	Output	16-bit timer/event counter 0 output.	Input	P70/TI00
TO50		8-bit timer/event counter 50 output (shared with 8-bit PWM output).	Input	P72/TI50
TO51		8-bit timer/event counter 51 output (shared with 8-bit PWM output).		P73/TI51
PCL	Output	Clock output (for trimming of main system clock and subsystem clock).	Input	P74
BUZ	Output	Buzzer output.	Input	P75
AD0 to AD7	I/O	Lower address/data bus for extending memory externally.	Input	P40 to P47

**Notes 1.** SI31, SO31, and  $\overline{\text{SCK31}}$  are incorporated only in the  $\mu$ PD78F0034A Subseries.

2. SDA0 and SCL0 are incorporated only in the  $\mu$ PD78F0034AY Subseries.



# 3.2 Non-Port Pins (2/2)

Pin Name	I/O	Function	After Reset	Alternate Function
A8 to A15	Output	Higher address bus for extending memory externally.	Input	P50 to P57
RD	Output	Strobe signal output for read operation of external memory.	Input	P64
WR		Strobe signal output for write operation of external memory.		P65
WAIT	Input	Inserting wait for accessing external memory.	Input	P66
ASTB	Output	Strobe output which externally latches address information output to ports 4 and 5 to access external memory.	Input	P67
ANI0 to ANI7	Input	A/D converter analog input.	Input	P10 to P17
ADTRG	Input	A/D converter trigger signal input.	Input	P03/INTP3
AVREF	Input	A/D converter reference voltage input.	_	_
AVDD	_	A/D converter analog power supply.  Set the voltage equal to VDDD or VDD1.	-	_
AVss	-	A/D converter ground potential.  Set the voltage equal to Vsso or Vss1.	_	_
RESET	Input	System reset input.	_	_
X1	Input	Connecting crystal resonator for main system clock oscillation.	_	_
X2	-		_	_
XT1	Input	Connecting crystal resonator for subsystem clock oscillation.	-	_
XT2	_		_	_
V <sub>DD0</sub>	-	Positive power supply voltage for ports.	_	_
Vsso	-	Ground potential of ports.	_	_
V <sub>DD1</sub>	_	Positive power supply (except ports).	_	-
V <sub>SS1</sub>	-	Ground potential (except ports).	_	_
V <sub>PP</sub>	-	Applying high-voltage for program write/verify. Connect directly to Vsso or Vss1 in normal operation mode.	_	_

# 3.3 Pin I/O Circuits and Recommended Connection of Unused Pins

The input/output circuit type of each pin and recommended connection of unused pins are shown in Table 3-1. For the input/output configuration of each type, refer to Figure 3-1.

Table 3-1. Types of Pin I/O Circuits (1/2)

Pin Name	I/O Circuit Type	I/O	Recommended Connection of Unused Pins
P00/INTP0	8-C	I/O	Input: Independently connect to V <sub>SS0</sub> via a resistor.
P01/INTP1			Output: Leave open.
P02/INTP2			
P03/INTP3/ADTRG			
P10/ANI0 to P17/ANI7	25	Input	Directly connect to VDD0 or VSS0.
P20/SI30	8-C	I/O	Input: Independently connect to VDD0 or VSS0 via a
P21/SO30	5-H		resistor.
P22/SCK30	8-C		Output: Leave open.
P23/RxD0			
P24/TxD0	5-H		
P25/ASCK0	8-C		
P30, P31	13-P	I/O	Input: Independently connect to VDDO via a resistor.
P32/SDA0 <sup>Note 1</sup>	13-R		Output: Leave open.
P33/SCL0 <sup>Note 1</sup>			
P34/SI31Note 2	8-C		Input: Independently connect to VDD0 or VSS0 via a
P35/SO31 <sup>Note 2</sup>	5-H		resistor.
P36/SCK31Note 2	8-C		Output: Leave open.
P40/AD0 to P47/AD7	5-H	I/O	Input: Independently connect to VDDO via a resistor.  Output: Leave open.
P50/A8 to P57/A15	5-H	I/O	Input: Independently connect to VDD0 or VSS0 via a
P64/RD		I/O	resistor.
P65/WR			Output: Leave open.
P66/WAIT			
P67/ASTB			
P70/TI00/TO0	8-C		
P71/TI01			
P72/TI50/TO50			
P73/TI51/TO51			
P74/PCL	5-H		
P75/BUZ			

**Notes 1.** SDA0 and SCL0 are incorporated only in the  $\mu$ PD78F0034AY Subseries.

2. SI31, SO31, and  $\overline{\text{SCK31}}$  are incorporated only in the  $\mu\text{PD78F0034A}$  Subseries.

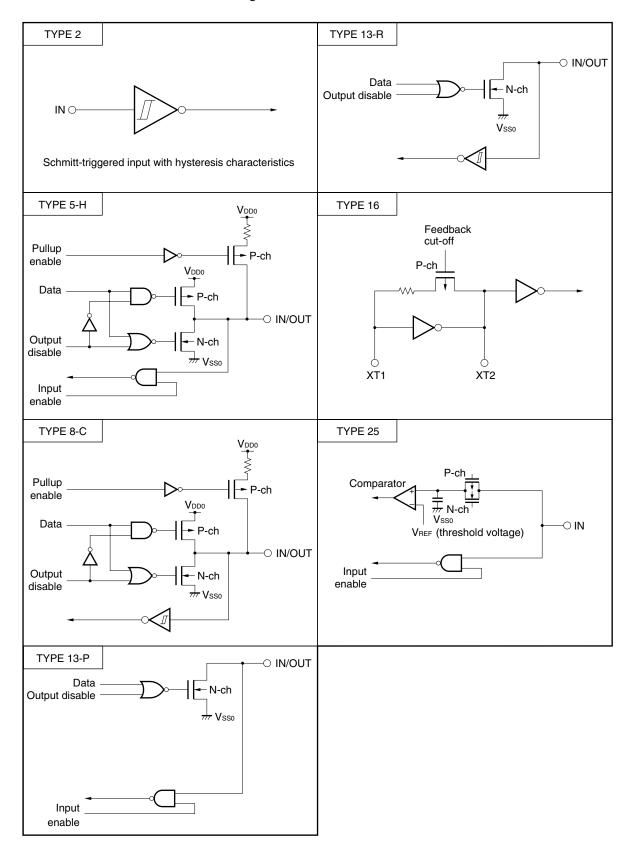
www.DataSheet4U.com

# Table 3-1. Types of Pin I/O Circuits (2/2)

Pin Name	I/O Circuit Type	I/O	Recommended Connection of Unused Pins
RESET	2	Input	-
XT1	16		Directly connect to VDD0.
XT2		_	Leave open.
AVDD	-		Directly connect to VDD0 or VDD1.
AVREF			Directly connect to Vsso or Vss1.
AVss			
V <sub>PP</sub>			Directly connect to Vsso or Vss1.



Figure 3-1. Pin I/O Circuits



#### ♦ 4. DIFFERENCES BETWEEN μPD78F0034A, 78F0034AY, AND MASK ROM VERSIONS

The  $\mu$ PD78F0034A and 78F0034AY are products provided with a flash memory which enables writing, erasing, and rewriting of programs with device mounted on the target system.

The functions of the  $\mu$ PD78F0034A (except the functions specified for flash memory) can be made the same as those of the mask ROM versions by setting the memory size switching register (IMS).

Tables 4-1 and 4-2 show the differences between the  $\mu$ PD78F0034A, 78F0034AY and the mask ROM versions.

Table 4-1. Differences Between  $\mu$ PD78F0034A and Mask ROM Versions

Item	μPD78F0034A	Mask ROM Versions			
		μPD780034A Subseries	μPD780024A Subseries <sup>Note</sup>		
Internal ROM structure	Flash memory	Mask ROM			
Internal ROM capacity	32 KB	μPD780031A: 8 KB μPD780032A: 16 KB μPD780033A: 24 KB μPD780034A: 32 KB	μPD780021A: 8 KB μPD780022A: 16 KB μPD780023A: 24 KB μPD780024A: 32 KB		
Internal high-speed RAM capacity	1,024 bytes	μPD780031A: 512 bytes μPD780032A: 512 bytes μPD780033A: 1,024 bytes μPD780034A: 1,024 bytes	μPD780021A: 512 bytes μPD780022A: 512 bytes μPD780023A: 1,024 bytes μPD780024A: 1,024 bytes		
Minimum instruction execution time	Minimum instruction execution	on time variable function inco	rporated		
When main system clock is selected	0.24 $\mu$ s/0.48 $\mu$ s/0.95 $\mu$ s/ 1.91 $\mu$ s/3.81 $\mu$ s (operation at 8.38 MHz, V <sub>DD</sub> = 4.0 to 5.5 V)	0.166 $\mu$ s/0.333 $\mu$ s/0.666 $\mu$ s/1.33 $\mu$ s/2.66 $\mu$ s (operation at 12 MHz, V <sub>DD</sub> = 4.5 to 5.5 V)			
When subsystem clock is selected	122 μs (32.768 kHz)				
Clock output	65.5 kHz, 131 kHz, 262 kHz, 524 kHz, 1.05 MHz, 2.10 MHz, 4.19 MHz, 8.38 MHz (operation at 8.38 MHz with main system clock)     32.768 kHz (operation at 32.768 kHz with subsystem clock)	93.75 kHz, 187.5 kHz, 375 kHz, 750 kHz, 1.25 MHz, 3 MHz, 6 MHz, 12 MHz (operation at 12 MHz with main system clock) 32.768 kHz (operation at 32.768 kHz with subsystem clock)			
Buzzer output	1.02 kHz, 2.5 kHz, 4.10 kHz, 8.19 kHz (operation at 8.38 MHz with main system clock)	1.46 kHz, 2.93 kHz, 5.86 kHz, 11.7 kHz (operation at 12 MHz with main system clock)			
A/D converter resolution	10 bits		8 bits		
Mask option specification of on-chip pull-up resistor for pins P30 to P33	Not available	Available			
IC pin	Not provided	Provided			
V <sub>PP</sub> pin	Provided	Not provided			
Electrical specifications, recommended soldering conditions	Refer to the data sheet of ir	individual products.			

**Note** The  $\mu$ PD78F0034A can be used as the flash memory version of the  $\mu$ PD780024A Subseries.

Caution There are differences in noise immunity and noise radiation between the flash memory and mask ROM versions. When pre-producing an application set with the flash memory version and then mass producing it with the mask ROM version, be sure to conduct sufficient evaluations on the commercial samples (CS) (not engineering samples (ES)) of the mask ROM versions.

www.DataSneet4U.com

Table 4-2. Differences Between  $\mu$ PD78F0034AY and Mask ROM Versions

Item	μPD78F0034AY	Mask ROM	M Versions			
		μPD780034AY Subseries	μPD780024AY Subseries <sup>Note</sup>			
Internal ROM structure	Flash memory	Mask ROM				
Internal ROM capacity	32 KB	μPD780031AY: 8 KB       μPD780021AY: 8 KB         μPD780032AY: 16 KB       μPD780022AY: 16 KB         μPD780033AY: 24 KB       μPD780023AY: 24 KB         μPD780034AY: 32 KB       μPD780024AY: 32 KB				
Internal high-speed RAM capacity	1,024 bytes	$\mu$ PD780031AY: 512 bytes $\mu$ PD780032AY: 512 bytes $\mu$ PD780033AY: 1,024 bytes $\mu$ PD780034AY: 1,024 bytes	μPD780021AY: 512 bytes μPD780022AY: 512 bytes μPD780023AY: 1,024 bytes μPD780024AY: 1,024 bytes			
Minimum instruction execution time	Minimum instruction execution	on time variable function inco	rporated			
When main system clock is selected	0.24 $\mu$ s/0.48 $\mu$ s/0.95 $\mu$ s/1.91 $\mu$ s/3.81 $\mu$ s (operation at 8.38 MHz, $V_{DD} = 4.0$ to 5.5 V)					
When subsystem clock is selected	122 μs (32.768 kHz)					
Clock output	<ul> <li>65.5 kHz, 131 kHz, 262 kH (operation at 8.38 MHz with 32.768 kHz (operation at 32.768 kHz with second sec</li></ul>	,	MHz, 4.19 MHz, 8.38 MHz			
Buzzer output	1.02 kHz, 2.5 kHz, 4.10 kHz (operation at 8.38 MHz with	·				
A/D converter resolution	10 bits		8 bits			
Mask option specification of on-chip pull-up resistor for pins P30 and P31	Not available	Available				
IC pin	Not provided	Provided				
V <sub>PP</sub> pin	Provided	Not provided				
Electrical specifications, recommended soldering conditions	Refer to the data sheet of in	f individual products.				

**Note** The  $\mu$ PD78F0034AY can be used as the flash memory version of the  $\mu$ PD780024AY Subseries.

Caution There are differences in noise immunity and noise radiation between the flash memory and mask ROM versions. When pre-producing an application set with the flash memory version and then mass producing it with the mask ROM version, be sure to conduct sufficient evaluations on the commercial samples (CS) (not engineering samples (ES)) of the mask ROM versions.

# 5. MEMORY SIZE SWITCHING REGISTER (IMS)

IMS is a register that is set by software and is used to specify a part of the internal memory that is not to be used. By setting memory size switching register (IMS), the internal memory of the  $\mu$ PD78F0034A and 78F0034AY can be mapped identically to that of a mask ROM version.

IMS is set with an 8-bit memory manipulation instruction.

RESET input sets IMS to CFH.

Caution The initial value of IMS is setting disabled (CFH). Be sure to set C8H or the value of the target mask ROM version at the moment of initial setting.

5 3 2 0 Address After reset R/W IMS RAM0 0 ROM3 ROM2 ROM1 ROM0 FFF0H CFH RAM2 RAM1 R/W ROM3 ROM2 ROM1 ROM0 Selection of Internal ROM Capacity 0 8 KB 0 1 0 0 1 0 0 16 KB 0 1 1 0 24 KB 1 0 0 32 KB Other than above Setting prohibited RAM2 RAM1 RAM0 Selection of Internal High-Speed RAM Capacity 0 0 1 512 bytes 0 1 1 1,024 bytes Other than above Setting prohibited

Figure 5-1. Format of Memory Size Switching Register

Table 5-1 shows the IMS set value to make the memory mapping the same as those of mask ROM versions.

Target Mask ROM Versions IMS Set Value

μPD780031A, 780031AY 42H

μPD780032A, 780032AY 44H

μPD780033A, 780033AY C6H

μPD780034A, 780034AY C8H

Table 5-1. Set Value of Memory Size Switching Register

#### 6. FLASH MEMORY PROGRAMMING

Writing to flash memory can be performed without removing the memory from the target system (on board programming). Writing is performed with the dedicated flash programmer (Flashpro III (part No.: FL-PR3 and PG-FP3)) connected to the host machine and the target system.

Writing to flash memory can also be performed using flash memory writing adapter connected to Flashpro III.

**Remark** FL-PR3 is a product of Naito Densei Machida Mfg. Co., Ltd.

#### 6.1 Selection of Communication Mode

Writing to a flash memory is performed using Flashpro III in a serial communication. Select one of the communication modes in Tables 6-1 and 6-2. The selection of the communication mode is made by using the format shown in Figure 6-1. Each communication mode is selected by the number of VPP pulses shown in Tables 6-1 and 6-2

Table 6-1. List of Communication Mode (μPD78F0034A)

Communication Mode	Channels	Pin Used	V <sub>PP</sub> Pulses
3-wire serial I/O	2	SI30/P20 SO30/P21 SCK30/P22	0
		SI31/P34 SO31/P35 SCK31/P36	1
UART	1	RxD0/P23 TxD0/P24	8
Pseudo 3-wire serial I/O	1	P72/TI50/TO50 (serial clock input) P71/TI01 (serial data output) P70/TI00/TO0 (serial data input)	12

Caution Be sure to select a communication mode using the number of VPP pulses shown in Table 6-1.

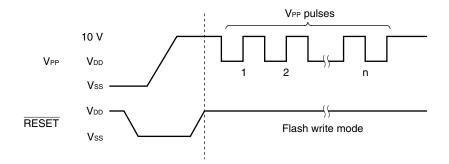
20 Data Sheet U14040EJ4V0DS www.DataSheet4U.com

Table 6-2. List of Communication Mode (μPD78F0034AY)

Communication Mode	Channels	Pin Used	V <sub>PP</sub> Pulses
3-wire serial I/O	1	SI30/P20 SO30/P21 SCK30/P22	0
I <sup>2</sup> C bus	1	SDA0/P32 SCL0/P33	4
UART	1	RxD0/P23 TxD0/P24	8
Pseudo 3-wire serial I/O	1	P72/TI50/TO50 (serial clock input) P71/TI01 (serial data output) P70/TI00/TO0 (serial data input)	12

Caution Be sure to select a communication mode using the number of VPP pulses shown in Table 6-2.

Figure 6-1. Format of Communication Mode Selection



#### 6.2 Flash Memory Programming Functions

Operations such as writing to flash memory are performed by various command/data transmission and reception operations according to the selected communication mode. Table 6-3 shows major functions of flash memory programming.

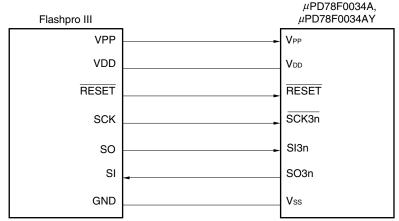
Table 6-3. Major Functions of Flash Memory Programming

Function	Description
Reset	Used to stop write operation and detect transmission cycle.
Batch verify	Compares the entire memory contents with the input data.
Batch erase	Erases the entire memory contents.
Batch blank check	Checks the deletion status of the entire memory.
High-speed write	Performs write to the flash memory based on the write start address and the number of data to be written (number of bytes).
Continuous write	Performs continuous write based on the information input with high-speed write operation.
Status	Used to confirm the current operating mode and operation end.
Oscillation frequency setting	Sets the frequency of the resonator.
Erase time setting	Sets the memory erase time.
Baud rate setting	Sets the communication rate for UART mode
I <sup>2</sup> C mode setting	Sets standard/high-speed mode for I <sup>2</sup> C bus mode
Silicon signature read	Outputs the device name and memory capacity, and device block information.

## 6.3 Connection of Flashpro III

The connection of Flashpro III and the  $\mu$ PD78F0034A or 78F0034AY differs according to the communication mode (3-wire serial I/O, UART, pseudo 3-wire serial I/O, and I<sup>2</sup>C bus). The connection for each communication mode is shown in Figures 6-2 to 6-5, respectively.

Figure 6-2. Connection of Flashpro III in 3-Wire Serial I/O Mode



**Remark**  $\mu$ PD78F0034A: n = 0, 1

 $\mu$ PD78F0034AY: n = 0



Figure 6-3. Connection of Flashpro III for UART Mode

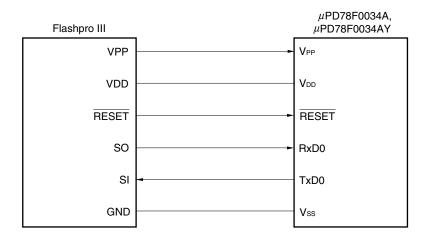


Figure 6-4. Connection of Flashpro III for Pseudo 3-Wire Serial I/O Mode

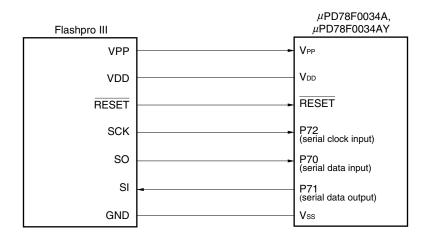
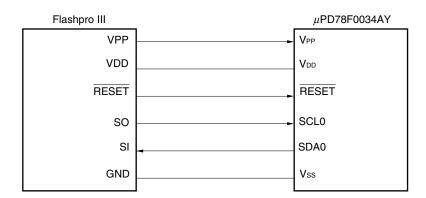


Figure 6-5. Connection of Flashpro III for I<sup>2</sup>C Bus Mode (μPD78F0034AY only)





# 7. ELECTRICAL SPECIFICATIONS

# Absolute Maximum Ratings (T<sub>A</sub> = 25°C)

Parameter	Symbol		Conditions	Ratings	Unit
Supply voltage	V <sub>DD</sub>			-0.3 to +6.5	V
	V <sub>PP</sub>			-0.3 to +10.5	V
	AVDD			-0.3 to V <sub>DD</sub> + 0.3 <sup>Note</sup>	V
	AVREF			-0.3 to V <sub>DD</sub> + 0.3 <sup>Note</sup>	V
AVs				-0.3 to +0.3	V
Input voltage	VII	·	10 to P17, P20 to P25, P34 to P36, 50 to P57, P64 to P67, P70 to P75, KT2, RESET	-0.3 to V <sub>DD</sub> + 0.3 <sup>Note</sup>	V
	V <sub>I2</sub>	P30 to P33	N-ch open drain	-0.3 to +6.5	V
Output voltage	Vo			-0.3 to V <sub>DD</sub> + 0.3 <sup>Note</sup>	٧
Analog input voltage	Van	P10 to P17	Analog input pin	AVss -0.3 to AV <sub>REF</sub> + 0.3 <sup>Note</sup> and -0.3 to V <sub>DD</sub> + 0.3 <sup>Note</sup>	V
Output current, high	Іон	Per pin		-10	mA
		Total for P00 to P03, P40 to P47, P50 to P57, P64 to P67, P70 to P75		-15	mA
		Total for P20 to P25, P30 to P36		-15	mA
Output current, low	Іоь		0 to P03, P20 to P25, P34 to P36, 64 to P67, P70 to P75	20	mA
		Per pin for P3	0 to P33, P50 to P57	30	mA
		Total for P00 P70 to P75	to P03, P40 to P47, P64 to P67,	50	mA
		Total for P20	to P25	20	mA
		Total for P30	to P36	100	mA
		Total for P50 to P57		100	mA
Operating ambient	TA	During norma	l operation	-40 to +85	°C
temperature		During flash n	nemory programming	+10 to +40	°C
Storage temperature	Tstg			-40 to +125	°C

Note 6.5 V or below

Caution Product quality may suffer if the absolute maximum rating is exceeded even momentarily for any parameter. That is, the absolute maximum ratings are rated values at which the product is on the verge of suffering physical damage, and therefore the product must be used under conditions that ensure that the absolute maximum ratings are not exceeded.



#### Capacitance (TA = $25^{\circ}$ C, V<sub>DD</sub> = Vss = 0 V)

Parameter	Symbol	Cor	nditions	MIN.	TYP.	MAX.	Unit
Input capacitance	Сім	f = 1 MHz Unmeasured pins returned to 0 V.				15	pF
I/O capacitance	Сю	f = 1 MHz Unmeasured pins returned to 0 V.	Unmeasured pins P34 to P36, P40 to P47,			15	pF
			P30 to P33			20	pF

Remark Unless otherwise specified, the characteristics of alternate-function pins are the same as those of port pins.

## Main System Clock Oscillator Characteristics (TA = -40 to +85°C, VDD = 1.8 to 5.5 V)

Resonator	Recommended Circuit	Parameter	Conditions	MIN.	TYP.	MAX.	Unit
Ceramic	V <sub>PP</sub> X2 X1	Oscillation	V <sub>DD</sub> = 4.0 to 5.5 V	1.0		8.38	MHz
resonator		frequency (fx)Note 1	V <sub>DD</sub> = 1.8 to 5.5 V	1.0		5.0	
	C2+ C1+	Oscillation stabilization time <sup>Note 2</sup>	After V <sub>DD</sub> reaches oscillation voltage range MIN.			4	ms
Crystal	V <sub>PP</sub> X2 X1	frequency (fy)Note 1	V <sub>DD</sub> = 4.0 to 5.5 V	1.0		8.38	MHz
resonator	or HIII		V <sub>DD</sub> = 1.8 to 5.5 V	1.0		5.0	
	C2 + C1 +	Oscillation	V <sub>DD</sub> = 4.0 to 5.5 V			10	ms
	777	stabilization time <sup>Note 2</sup>	V <sub>DD</sub> = 1.8 to 5.5 V			30	
External	X2 X1	X1 input	V <sub>DD</sub> = 4.0 to 5.5 V	1.0		8.38	MHz
clock	μPD74HCU04 Δ	frequency (fx)Note 1	V <sub>DD</sub> = 1.8 to 5.5 V	1.0		5.0	
		X1 input high-/low-level	V <sub>DD</sub> = 4.0 to 5.5 V	50		500	ns
		width (tхн, tхь)	V <sub>DD</sub> = 1.8 to 5.5 V	85		500	

Notes 1. Indicates only oscillator characteristics. Refer to AC Characteristics for instruction execution time.

2. Time required to stabilize oscillation after reset or STOP mode release.

Cautions 1. When using the main system clock oscillator, wire as follows in the area enclosed by the broken lines in the above figures to avoid an adverse effect from wiring capacitance.

- · Keep the wiring length as short as possible.
- Do not cross the wiring with the other signal lines.
- . Do not route the wiring near a signal line through which a high fluctuating current flows.
- Always make the ground point of the oscillator capacitor to the same potential as Vss1.
- . Do not ground the capacitor to a ground pattern through which a high current flows.
- Do not fetch signals from the oscillator.
- 2. When the main system clock is stopped and the system is operating on the subsystem clock, wait until the oscillation stabilization time has been secured by the program before switching back to the main system clock.

#### Subsystem Clock Oscillator Characteristics ( $T_A = -40 \text{ to } +85^{\circ}\text{C}$ , $V_{DD} = 1.8 \text{ to } 5.5 \text{ V}$ )

Resonator	Recommended Circuit	Parameter	Conditions	MIN.	TYP.	MAX.	Unit
Crystal resonator	XT2 XT1V <sub>PP</sub>	Oscillation frequency (fxr)Note 1		32	32.768	35	kHz
	+C4 +C3	Oscillation	V <sub>DD</sub> = 4.0 to 5.5 V		1.2	2	s
		stabilization time <sup>Note 2</sup>	V <sub>DD</sub> = 1.8 to 5.5 V			10	
External clock	XT2 XT1	X1 input frequency (fxT)Note 1		32		38.5	kHz
	μPD74HCU04	X1 input high-/low-level width (txth, txtl)		5		15	μs

- Notes 1. Indicates only oscillator characteristics. Refer to AC Characteristics for instruction execution time.
  - 2. Time required to stabilize oscillation after VDD reaches oscillator voltage MIN.
- Cautions 1. When using the subsystem clock oscillator, wire as follows in the area enclosed by the broken lines in the above figures to avoid an adverse effect from wiring capacitance.
  - · Keep the wiring length as short as possible.
  - Do not cross the wiring with the other signal lines.
  - Do not route the wiring near a signal line through which a high fluctuating current flows.
  - Always make the ground point of the oscillator capacitor to the same potential as Vss1.
  - Do not ground the capacitor to a ground pattern through which a high current flows.
  - · Do not fetch signals from the oscillator.
  - 2. The subsystem clock oscillator is designed as a low-amplitude circuit for reducing current consumption, and is more prone to malfunction due to noise than the main system clock oscillator. Particular care is therefore required with the wiring method when the subsystem clock is used.

#### **Recommended Oscillator Constant**

## Main System Clock: Ceramic Resonator (T<sub>A</sub> = −40 to +85°C)

CSBLA1M00J58         1.00         100         100         2.2         1.9         5.5           CSTCC2M00G56         2.00         On chip         On chip         0         1.8         5.5           CSTLS2M00G56         2.00         On chip         On chip         0         1.8         5.5           CSTCC3M58G53         3.58         On chip         On chip         0         1.8         5.5           CSTLS3M58G53         3.58         On chip         On chip         0         1.8         5.5           CSTCR4M00G53         4.00         On chip         On chip         0         1.8         5.5           CSTLS4M00G53         4.00         On chip         On chip         0         1.8         5.5           CSTLS4M19G53         4.19         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLSM00G53         5.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53 <t< th=""><th>Manufacturer</th><th>Part Number</th><th>Frequency</th><th>Recommo</th><th>ended Circuit</th><th>Constant</th><th colspan="3">Oscillation Voltage Range</th></t<>	Manufacturer	Part Number	Frequency	Recommo	ended Circuit	Constant	Oscillation Voltage Range		
CSBLA1M00J58         1.00         100         100         2.2         1.9         5.5           CSTCC2M00G56         2.00         On chip         On chip         0         1.8         5.5           CSTLS2M00G56         2.00         On chip         On chip         0         1.8         5.5           CSTCC3M58G53         3.58         On chip         On chip         0         1.8         5.5           CSTCR4M00G53         4.00         On chip         On chip         0         1.8         5.5           CSTLS4M00G53         4.00         On chip         On chip         0         1.8         5.5           CSTLS4M19G53         4.19         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.19         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         5.00         On chip         On chip         0         2.7         5.5           CSTLS4M09G53         <			(MHz)	C1 (pF)	C2 (pF)	R1 (kΩ)	MIN. (V)	MAX. (V)	
CSTCC2M00G56         2.00         On chip         On chip         0         1.8         5.5           CSTLS2M00G56         2.00         On chip         On chip         0         1.8         5.5           CSTCC3M58G53         3.58         On chip         On chip         0         1.8         5.5           CSTCR4M00G53         4.00         On chip         On chip         0         1.8         5.5           CSTCR4M09G53         4.00         On chip         On chip         0         1.8         5.5           CSTCR4M19G53         4.19         On chip         On chip         0         1.8         5.5           CSTCR4M91G53         4.19         On chip         On chip         0         1.8         5.5           CSTCR4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTCR4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTCR5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTCSM00G53         5.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53093	Murata Mg. Co., Ltd.	CSBFB1M00J58	1.00	100	100	2.2	1.9	5.5	
CSTLS2M00G56         2.00         On chip         On chip         0         1.8         5.5           CSTCC3M58G53         3.58         On chip         On chip         0         1.8         5.5           CSTLS3M58G53         3.58         On chip         On chip         0         1.8         5.5           CSTCR4M00G53         4.00         On chip         On chip         0         1.8         5.5           CSTLS4M19G53         4.19         On chip         On chip         0         1.8         5.5           CSTLS4M19G53         4.19         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         2.7         5.5           CSTLS5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53		CSBLA1M00J58	1.00	100	100	2.2	1.9	5.5	
CSTCC3M58G53         3.58         On chip         On chip         0         1.8         5.5           CSTLS3M58G53         3.58         On chip         On chip         0         1.8         5.5           CSTCR4M00G53         4.00         On chip         On chip         0         1.8         5.5           CSTLS4M00G53         4.00         On chip         On chip         0         1.8         5.5           CSTCR4M19G53         4.19         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.19         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         2.7         5.5           CSTLS5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53		CSTCC2M00G56	2.00	On chip	On chip	0	1.8	5.5	
CSTLS3M58G53         3.58         On chip         On chip         0         1.8         5.5           CSTCR4M00G53         4.00         On chip         On chip         0         1.8         5.5           CSTLS4M00G53         4.00         On chip         On chip         0         1.8         5.5           CSTCR4M19G53         4.19         On chip         On chip         0         1.8         5.5           CSTCR4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         2.7         5.5           CSTLS8M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53093		CSTLS2M00G56	2.00	On chip	On chip	0	1.8	5.5	
CSTCR4M00G53         4.00         On chip         On chip         0         1.8         5.5           CSTLS4M00G53         4.00         On chip         On chip         0         1.8         5.5           CSTCR4M19G53         4.19         On chip         On chip         0         1.8         5.5           CSTCR4M91G53         4.19         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTLS5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M0G53		CSTCC3M58G53	3.58	On chip	On chip	0	1.8	5.5	
CSTLS4M00G63         4.00         On chip         On chip         0         1.8         5.5           CSTCR4M19G53         4.19         On chip         On chip         0         1.8         5.5           CSTLS4M19G53         4.19         On chip         On chip         0         1.8         5.5           CSTCR4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTCR5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTCE8M00G52         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M3G53         8.30         On chip         On chip         0         2.7         5.5           CSTLS8M3G53         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M3G53093         8.38         On chip         On chip         0         3.0         5.5           CSTLS1MM0G52		CSTLS3M58G53	3.58	On chip	On chip	0	1.8	5.5	
CSTCR4M19G53 4.19 On chip On chip 0 1.8 5.5  CSTLS4M19G53 4.19 On chip On chip 0 1.8 5.5  CSTCR4M91G53 4.91 On chip On chip 0 1.8 5.5  CSTCR4M91G53 4.91 On chip On chip 0 1.8 5.5  CSTCR5M00G53 4.91 On chip On chip 0 2.7 5.5  CSTCR5M00G53 5.00 On chip On chip 0 2.7 5.5  CSTCE8M00G52 8.00 On chip On chip 0 2.7 5.5  CSTLS8M00G53 8.00 On chip On chip 0 2.7 5.5  CSTLS8M00G53 8.00 On chip On chip 0 2.7 5.5  CSTLS8M00G53 8.00 On chip On chip 0 2.7 5.5  CSTLS8M00G53 8.00 On chip On chip 0 3.0 5.5  CSTLS8M38G52 8.38 On chip On chip 0 3.0 5.5  CSTLS8M38G53 8.38 On chip On chip 0 3.0 5.5  CSTLS8M38G53 8.38 On chip On chip 0 3.0 5.5  CSTLS8M38G53 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53 10.00 On chip On chip 0 4.5 5.5  CSTCE12M0G52 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CSTLA19MC3 4.19 On-chip On-chip 0 1.8 5.5  CCR6.0MC3 5.00 On-chip On-chip 0 1.8 5.5  CCR6.0MC5 8.00 On-chip On-chip 0 1.8 5.5		CSTCR4M00G53	4.00	On chip	On chip	0	1.8	5.5	
CSTLS4M19G53 4.19 On chip On chip 0 1.8 5.5  CSTCR4M91G53 4.91 On chip On chip 0 1.8 5.5  CSTLS4M91G53 4.91 On chip On chip 0 1.8 5.5  CSTLS4M91G53 4.91 On chip On chip 0 1.8 5.5  CSTCR5M00G53 5.00 On chip On chip 0 2.7 5.5  CSTLS5M00G53 5.00 On chip On chip 0 2.7 5.5  CSTCEBM00G52 8.00 On chip On chip 0 2.7 5.5  CSTLS8M00G53 8.00 On chip On chip 0 2.7 5.5  CSTLS8M00G53 8.00 On chip On chip 0 2.7 5.5  CSTLS8M00G53093 8.00 On chip On chip 0 2.7 5.5  CSTLS8M38G52 8.38 On chip On chip 0 3.0 5.5  CSTLS8M38G53 8.38 On chip On chip 0 3.0 5.5  CSTLS8M38G53 8.38 On chip On chip 0 3.0 5.5  CSTLS10M0G52 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53 12.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 1.8 5.5  CCR4.19MC3 4.19 On-chip On-chip 0 1.8 5.5  CCR5.0MC3 5.00 On-chip On-chip 0 1.8 5.5  CCR8.0MCS 8.00 On-chip On-chip 0 5.5		CSTLS4M00G53	4.00	On chip	On chip	0	1.8	5.5	
CSTCR4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTCR5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTLS5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTCE8M00G52         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53093         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M38G53         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M38G53093         8.38         On chip         On chip         0         3.0         5.5           CSTLS10M0G52         10.00         On chip         On chip         0         4.5         5.5           CSTLS10M0G53         10.00         On chip         On chip         0         4.5         5.5           CSTLA12M0G52<		CSTCR4M19G53	4.19	On chip	On chip	0	1.8	5.5	
CSTLS4M91G53         4.91         On chip         On chip         0         1.8         5.5           CSTCR5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTLS5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTCE8M00G52         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53093         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M38G52         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M38G53         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M38G53093         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M38G53093         8.38         On chip         On chip         0         3.0         5.5           CSTLS10M0G52         10.00         On chip         On chip         0         4.5         5.5           CSTLS10M0G53         10.00         On chip         On chip         0         4.5         5.5           CSTCE12M0G		CSTLS4M19G53	4.19	On chip	On chip	0	1.8	5.5	
CSTCR5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTLS5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTCE8M00G52         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M30G53093         8.00         On chip         On chip         0         2.7         5.5           CSTCE8M38G52         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M38G53093         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M38G53093         8.38         On chip         On chip         0         3.0         5.5           CSTLS10M0G52         10.00         On chip         On chip         0         4.5         5.5           CSTLS10M0G53         10.00         On chip         On chip         0         4.5         5.5           CSTCE12M0G52         12.00         On chip         On chip         0         4.5         5.5           CSTLA12M0		CSTCR4M91G53	4.91	On chip	On chip	0	1.8	5.5	
CSTLS5M00G53         5.00         On chip         On chip         0         2.7         5.5           CSTCEBM00G52         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53093         8.00         On chip         On chip         0         2.7         5.5           CSTCEBM38G52         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M38G53         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M38G53093         8.38         On chip         On chip         0         3.0         5.5           CSTCE10M0G52         10.00         On chip         On chip         0         4.5         5.5           CSTLS10M0G53         10.00         On chip         On chip         0         4.5         5.5           CSTLS10M0G53093         10.00         On chip         On chip         0         4.5         5.5           CSTLA12M0T550         12.00         On chip         On chip         0         4.5         5.5           CSTLA12		CSTLS4M91G53	4.91	On chip	On chip	0	1.8	5.5	
CSTCE8M00G52 8.00 On chip On chip 0 2.7 5.5  CSTLS8M00G53 8.00 On chip On chip 0 2.7 5.5  CSTLS8M00G53093 8.00 On chip On chip 0 2.7 5.5  CSTCE8M38G52 8.38 On chip On chip 0 3.0 5.5  CSTLS8M38G53 8.38 On chip On chip 0 3.0 5.5  CSTLS8M38G53 8.38 On chip On chip 0 3.0 5.5  CSTLS8M38G53093 8.38 On chip On chip 0 3.0 5.5  CSTCE10M0G52 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53 10.00 On chip On chip 0 4.5 5.5  CSTCE12M0G52 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CCR4.19MC3 4.19 On-chip On-chip 0 1.8 5.5  CCR5.0MC3 5.00 On-chip On-chip 0 4.0 5.5		CSTCR5M00G53	5.00	On chip	On chip	0	2.7	5.5	
CSTLS8M00G53         8.00         On chip         On chip         0         2.7         5.5           CSTLS8M00G53093         8.00         On chip         On chip         0         2.7         5.5           CSTCE8M38G52         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M38G53         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M38G53093         8.38         On chip         On chip         0         3.0         5.5           CSTLS10M0G52         10.00         On chip         On chip         0         4.5         5.5           CSTLS10M0G53         10.00         On chip         On chip         0         4.5         5.5           CSTLS10M0G53093         10.00         On chip         On chip         0         4.5         5.5           CSTLA12M0T55         12.00         On chip         On chip         0         4.5         5.5           CSTLA12M0T55093         12.00         On chip         On chip         0         4.5         5.5           CCR4.19MC3         3.58         On-chip         On-chip         0         1.8         5.5           CCR5.0		CSTLS5M00G53	5.00	On chip	On chip	0	2.7	5.5	
CSTLS8M00G53093         8.00         On chip         On chip         0         2.7         5.5           CSTCE8M38G52         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M38G53         8.38         On chip         On chip         0         3.0         5.5           CSTLS8M38G53093         8.38         On chip         On chip         0         3.0         5.5           CSTCE10M0G52         10.00         On chip         On chip         0         4.5         5.5           CSTLS10M0G53         10.00         On chip         On chip         0         4.5         5.5           CSTLS10M0G53093         10.00         On chip         On chip         0         4.5         5.5           CSTCE12M0G52         12.00         On chip         On chip         0         4.5         5.5           CSTLA12M0T55         12.00         On chip         On chip         0         4.5         5.5           CSTLA12M0T55093         12.00         On chip         On chip         0         4.5         5.5           CCR3.58MC3         3.58         On-chip         On-chip         0         1.8         5.5           CCR5.		CSTCE8M00G52	8.00	On chip	On chip	0	2.7	5.5	
CSTCE8M38G52 8.38 On chip On chip 0 3.0 5.5  CSTLS8M38G53 8.38 On chip On chip 0 3.0 5.5  CSTLS8M38G53093 8.38 On chip On chip 0 3.0 5.5  CSTCE10M0G52 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53093 10.00 On chip On chip 0 4.5 5.5  CSTCE12M0G52 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CCR4.19MC3 4.19 On-chip On-chip 0 1.8 5.5  CCR5.0MC3 5.00 On-chip On-chip 0 1.8 5.5  CCR8.0MC5 8.00 On-chip On-chip 0 4.0 5.5		CSTLS8M00G53	8.00	On chip	On chip	0	2.7	5.5	
CSTLS8M38G53 8.38 On chip On chip 0 3.0 5.5  CSTLS8M38G53093 8.38 On chip On chip 0 3.0 5.5  CSTCE10M0G52 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53093 10.00 On chip On chip 0 4.5 5.5  CSTCE12M0G52 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CCR3.58MC3 3.58 On-chip On-chip 0 1.8 5.5  CCR4.19MC3 4.19 On-chip On-chip 0 1.8 5.5  CCR5.0MC3 5.00 On-chip On-chip 0 1.8 5.5  CCR8.0MC5 8.00 On-chip On-chip 0 4.0 5.5		CSTLS8M00G53093	8.00	On chip	On chip	0	2.7	5.5	
CSTLS8M38G53093 8.38 On chip On chip 0 3.0 5.5  CSTCE10M0G52 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53093 10.00 On chip On chip 0 4.5 5.5  CSTCE12M0G52 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 5.5  TDK  CCR3.58MC3 3.58 On-chip On-chip 0 1.8 5.5  CCR4.19MC3 4.19 On-chip On-chip 0 1.8 5.5  CCR5.0MC3 5.00 On-chip On-chip 0 1.8 5.5  CCR8.0MC5 8.00 On-chip On-chip 0 5.5		CSTCE8M38G52	8.38	On chip	On chip	0	3.0	5.5	
CSTCE10M0G52 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53093 10.00 On chip On chip 0 4.5 5.5  CSTCE12M0G52 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CCR3.58MC3 3.58 On-chip On-chip 0 1.8 5.5  CCR4.19MC3 4.19 On-chip On-chip 0 1.8 5.5  CCR5.0MC3 5.00 On-chip On-chip 0 1.8 5.5  CCR8.0MC5 8.00 On-chip On-chip 0 5.5		CSTLS8M38G53	8.38	On chip	On chip	0	3.0	5.5	
CSTLS10M0G53 10.00 On chip On chip 0 4.5 5.5  CSTLS10M0G53093 10.00 On chip On chip 0 4.5 5.5  CSTCE12M0G52 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CCR3.58MC3 3.58 On-chip On-chip 0 1.8 5.5  CCR4.19MC3 4.19 On-chip On-chip 0 1.8 5.5  CCR5.0MC3 5.00 On-chip On-chip 0 1.8 5.5  CCR8.0MC5 8.00 On-chip On-chip 0 4.0 5.5		CSTLS8M38G53093	8.38	On chip	On chip	0	3.0	5.5	
CSTLS10M0G53093 10.00 On chip On chip 0 4.5 5.5  CSTCE12M0G52 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  TDK  CCR3.58MC3 3.58 On-chip On-chip 0 1.8 5.5  CCR4.19MC3 4.19 On-chip On-chip 0 1.8 5.5  CCR5.0MC3 5.00 On-chip On-chip 0 1.8 5.5  CCR8.0MC5 8.00 On-chip On-chip 0 5.5		CSTCE10M0G52	10.00	On chip	On chip	0	4.5	5.5	
CSTCE12M0G52 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  TDK  CCR3.58MC3 3.58 On-chip On-chip 0 1.8 5.5  CCR4.19MC3 4.19 On-chip On-chip 0 1.8 5.5  CCR5.0MC3 5.00 On-chip On-chip 0 1.8 5.5  CCR8.0MC5 8.00 On-chip On-chip 0 5.5		CSTLS10M0G53	10.00	On chip	On chip	0	4.5	5.5	
CSTLA12M0T55 12.00 On chip On chip 0 4.5 5.5  CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  TDK  CCR3.58MC3 3.58 On-chip On-chip 0 1.8 5.5  CCR4.19MC3 4.19 On-chip On-chip 0 1.8 5.5  CCR5.0MC3 5.00 On-chip On-chip 0 1.8 5.5  CCR8.0MC5 8.00 On-chip On-chip 0 5.5		CSTLS10M0G53093	10.00	On chip	On chip	0	4.5	5.5	
CSTLA12M0T55093 12.00 On chip On chip 0 4.5 5.5  TDK  CCR3.58MC3 3.58 On-chip On-chip 0 1.8 5.5  CCR4.19MC3 4.19 On-chip On-chip 0 1.8 5.5  CCR5.0MC3 5.00 On-chip On-chip 0 1.8 5.5  CCR8.0MC5 8.00 On-chip On-chip 0 5.5		CSTCE12M0G52	12.00	On chip	On chip	0	4.5	5.5	
CCR3.58MC3         3.58         On-chip         On-chip         0         1.8         5.5           CCR4.19MC3         4.19         On-chip         On-chip         0         1.8         5.5           CCR5.0MC3         5.00         On-chip         On-chip         0         1.8         5.5           CCR8.0MC5         8.00         On-chip         On-chip         0         4.0         5.5		CSTLA12M0T55	12.00	On chip	On chip	0	4.5	5.5	
CCR4.19MC3         4.19         On-chip         On-chip         0         1.8         5.5           CCR5.0MC3         5.00         On-chip         On-chip         0         1.8         5.5           CCR8.0MC5         8.00         On-chip         On-chip         0         4.0         5.5		CSTLA12M0T55093	12.00	On chip	On chip	0	4.5	5.5	
CCR5.0MC3         5.00         On-chip         On-chip         0         1.8         5.5           CCR8.0MC5         8.00         On-chip         On-chip         0         4.0         5.5	TDK	CCR3.58MC3	3.58	On-chip	On-chip	0	1.8	5.5	
CCR8.0MC5         8.00         On-chip         On-chip         0         4.0         5.5		CCR4.19MC3	4.19	On-chip	On-chip	0	1.8	5.5	
		CCR5.0MC3	5.00	On-chip	On-chip	0	1.8	5.5	
CCR8.38MC5         8.38         On-chip         On-chip         0         4.0         5.5		CCR8.0MC5	8.00	On-chip	On-chip	0	4.0	5.5	
		CCR8.38MC5	8.38	On-chip	On-chip	0	4.0	5.5	

Caution The oscillator constant and oscillation voltage range indicate conditions of stable oscillation.

Oscillation frequency precision is not guaranteed. For applications requiring oscillation frequency precision, the oscillation frequency must be adjusted on the implementation circuit. For details please contact directly the manufacturer of the resonator you will use.

#### www.DataSheet4U.com

# DC Characteristics (TA = -40 to $+85^{\circ}$ C, VDD = 1.8 to 5.5 V)

Parameter	Symbol	С	onditions	MIN.	TYP.	MAX.	Unit
Output current,	Іон	Per pin				-1	mA
high		All pins	All pins				mA
Output current, low	Іоь	Per pin for P00 to P03, P2 P40 to P47, P64 to P67, F				10	mA
		Per pin for P30 to P33, P50 to P57				15	mA
		Total for P00 to P03, P40	to P47, P64 to P67, P70 to P75			20	mA
		Total for P20 to P25				10	mA
		Total for P30 to P36				70	mA
		Total for P50 to P57				70	mA
Input voltage, high	V <sub>IH1</sub>	P10 to P17, P21, P24, P35, P40 to P47,	V <sub>DD</sub> = 2.7 to 5.5 V	0.7V <sub>DD</sub>		V <sub>DD</sub>	V
		P50 to P57, P64 to P67, P74, P75	V <sub>DD</sub> = 1.8 to 5.5 V	0.8V <sub>DD</sub>		V <sub>DD</sub>	V
	V <sub>IH2</sub>	P00 to P03, P20, P22, P23, P25, P34, P36,	V <sub>DD</sub> = 2.7 to 5.5 V	0.8V <sub>DD</sub>		V <sub>DD</sub>	V
		P70 to P73, RESET	V <sub>DD</sub> = 1.8 to 5.5 V	0.85V <sub>DD</sub>		V <sub>DD</sub>	V
	VIH3	P30 to P33	V <sub>DD</sub> = 2.7 to 5.5 V	0.7V <sub>DD</sub>		5.5	V
		(N-ch open-drain)		0.8V <sub>DD</sub>		5.5	V
	V <sub>IH4</sub>	X1, X2	V <sub>DD</sub> = 2.7 to 5.5 V	V <sub>DD</sub> - 0.5		V <sub>DD</sub>	V
			V <sub>DD</sub> = 1.8 to 5.5 V	V <sub>DD</sub> - 0.2		V <sub>DD</sub>	V
	V <sub>IH5</sub>	XT1, XT2	V <sub>DD</sub> = 4.0 to 5.5 V	0.8V <sub>DD</sub>		V <sub>DD</sub>	V
				0.9V <sub>DD</sub>		V <sub>DD</sub>	V
Input voltage,	V <sub>IL1</sub>	P10 to P17, P21, P24, P35, P40 to P47,	V <sub>DD</sub> = 2.7 to 5.5 V	0		0.3V <sub>DD</sub>	V
		P50 to P57, P64 to P67, P74, P75	V <sub>DD</sub> = 1.8 to 5.5 V	0		0.2V <sub>DD</sub>	V
	V <sub>IL2</sub>	P00 to P03, P20, P22, P23, P25, P34, P36,	V <sub>DD</sub> = 2.7 to 5.5 V	0		0.2V <sub>DD</sub>	V
		P70 to P73, RESET	V <sub>DD</sub> = 1.8 to 5.5 V	0		0.15V <sub>DD</sub>	V
	V <sub>IL3</sub>	P30 to P33	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V	0		0.3V <sub>DD</sub>	V
			2.7 V ≤ V <sub>DD</sub> < 4.0 V	0		0.2V <sub>DD</sub>	V
			1.8 V ≤ V <sub>DD</sub> < 2.7	0		0.1V <sub>DD</sub>	V
	V <sub>IL4</sub>	X1, X2	V <sub>DD</sub> = 2.7 to 5.5 V	0		0.4	V
			V <sub>DD</sub> = 1.8 to 5.5 V	0		0.2	V
	V <sub>IL5</sub>	XT1, XT2	V <sub>DD</sub> = 4.0 to 5.5 V	0		0.2VDD	V
			V <sub>DD</sub> = 1.8 to 5.5 V	0		0.1VDD	V
Output voltage,	V <sub>OH1</sub>	V <sub>DD</sub> = 4.0 to 5.5 V, I <sub>OH</sub> = -	1 mA	V <sub>DD</sub> - 1.0		V <sub>DD</sub>	V
high		Іон = -100 μΑ		V <sub>DD</sub> - 0.5		V <sub>DD</sub>	V
Output voltage,	V <sub>OL1</sub>	P30 to P33	V <sub>DD</sub> = 4.0 to 5.5 V, I <sub>OL</sub> = 15 mA			2.0	V
low		P50 to P57			0.4	2.0	V
		P00 to P03, P20 to P25, P34 to P36, P40 to P47, P64 to P67, P70 to P75	V <sub>DD</sub> = 4.0 to 5.5 V, I <sub>OL</sub> = 1.6 mA			0.4	V
	V <sub>OL2</sub>	IoL = 400 μA	1			0.5	V

**Remark** Unless otherwise specified, the characteristics of alternate-function pins are the same as those of port pins.

# DC Characteristics (T<sub>A</sub> = -40 to +85°C, V<sub>DD</sub> = 1.8 to 5.5 V)

Parameter	Symbol		Conditions	MIN.	TYP.	MAX.	Unit
Input leakage current, high	Ішн1	V <sub>IN</sub> = V <sub>DD</sub> P00 to P03, P10 to P17, P20 to P25, P34 to P36, P40 to P47, P50 to P57, P64 to P67, P70 to P75, RESET				3	μΑ
	I <sub>LIH2</sub>		X1, X2, XT1, XT2			20	μΑ
	Ішнз	V <sub>IN</sub> = 5.5 V	P30 to P33			3	μΑ
Input leakage current, low	ILIL1	V <sub>IN</sub> = 0 V P00 to P03, P10 to P17, P20 to P25, P34 to P36, P40 to P47, P50 to P57, P64 to P67, P70 to P75, RESET				-3	μΑ
	ILIL2		X1, X2, XT1, XT2			-20	μΑ
	Ішіз		P30 to P33			-3	μΑ
Output leakage current, high	Ісон	Vout = VDD				3	μΑ
Output leakage current, low	Ісос	Vout = 0 V				-3	μΑ
Software pull- up resistor	R	V <sub>IN</sub> = 0 V, P00 to P03, P20 to I P50 to P57, P64 to I	P25, P34 to P36, P40 to P47, P67, P70 to P75	15	30	90	kΩ

Remark Unless otherwise specified, the characteristics of alternate-function pins are the same as those of port pins.

#### www.DataSheet4U.com

# DC Characteristics (T<sub>A</sub> = -40 to +85°C, V<sub>DD</sub> = 1.8 to 5.5 V)

Parameter	Symbol		Conditions		MIN.	TYP.	MAX.	Unit
Supply	I <sub>DD1</sub>	8.38 MHz crystal	$V_{DD} = 5.0 \text{ V } \pm 10\%^{\text{Note 2}}$	A/D converter stopped		10.5	21	mA
current <sup>Note 1</sup>		oscillation operating mode		A/D converter operating		11.5	23	mA
	5.00 MHz crystal	$V_{DD} = 3.0 \text{ V } \pm 10\%^{\text{Note 2}}$	A/D converter stopped		4.5	9	mA	
		oscillation operation mode		A/D converter operating		5.5	11	mA
	V <sub>DD</sub> = 2.0 V ±1	$V_{DD} = 2.0 \text{ V } \pm 10\%^{\text{Note 3}}$	A/D converter stopped		1	2	mA	
				A/D converter operating		2	6	mA
	I <sub>DD2</sub>	oscillation HALT mode	$V_{DD} = 5.0 \text{ V } \pm 10\%$ Note 2	Peripheral functions stopped		1.2	2.4	mA
				Peripheral functions operating			5	mA
			$V_{DD} = 3.0 \text{ V } \pm 10\%^{\text{Note 2}}$	Peripheral functions stopped		0.4	0.8	mA
				Peripheral functions operating			1.7	mA
			$V_{DD} = 2.0 \text{ V } \pm 10\%^{\text{Note 3}}$	Peripheral functions stopped		0.2	0.4	mA
				Peripheral functions operating			1.1	mA
	I <sub>DD3</sub>	32.768 kHz crystal oscilla	tion operating mode <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V ±10%Note 2		115	230	μΑ
				V <sub>DD</sub> = 3.0 V ±10%Note 2		95	190	μΑ
				V <sub>DD</sub> = 2.0 V ±10%Note 3		75	150	μΑ
	I <sub>DD4</sub>	32.768 kHz crystal oscilla	ition HALT mode <sup>Note 4</sup>	V <sub>DD</sub> = 5.0 V ±10%Note 2		30	60	μΑ
				V <sub>DD</sub> = 3.0 V ±10%Note 2		6	18	μΑ
				V <sub>DD</sub> = 2.0 V ±10%Note 3		2	10	μΑ
	I <sub>DD5</sub>	XT1 = V <sub>DD</sub> , STOP mode		V <sub>DD</sub> = 5.0 V ±10%Note 2		0.1	30	μΑ
		When feed-back resistor not used	not used	V <sub>DD</sub> = 3.0 V ±10%Note 2		0.05	10	μΑ
				V <sub>DD</sub> = 2.0 V ±10%Note 3		0.05	10	μΑ

**Notes 1.** Refers to the total current flowing through the internal power supply (VDD0 and VDD1). Includes peripheral operating current (however, current flowing through the pull-up resistors of ports and the AVREF pin is not included).

- 2. When the processor clock control register (PCC) is set to 00H.
- 3. When PCC is set to 02H.
- 4. When the main system clock is stopped.

30 Data Sheet U14040EJ4V0DS www.DataSheet4U.com

#### **AC Characteristics**

## (1) Basic operation ( $T_A = -40 \text{ to } +85^{\circ}\text{C}$ , $V_{DD} = 1.8 \text{ to } 5.5 \text{ V}$ )

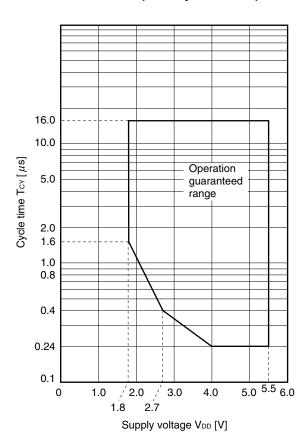
Parameter	Symbol	Conditions			MIN.	TYP.	MAX.	Unit
Cycle time (Min. instruction	Тсч	Operating on main system clock	4.0 ≤ V <sub>D</sub>	$_{DD} \leq 5.5 \text{ V}$	0.24		16	μs
			2.7 V ≤ V <sub>DD</sub> < 4.0 V		0.4		16	μs
execution time)			1.8 V ≤	V <sub>DD</sub> < 2.7 V	1.6		16	μs
		Operating on subsystem clock		103.9 <sup>Note 1</sup>	122	125	μs	
TI00, TI01 input	ttiho, ttilo	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V					μs
high-/low-level width		2.7 V ≤ V <sub>DD</sub> < 4.0 V			2/fsam + 0.2 <sup>Note 2</sup>			μs
			1.8 V ≤ V <sub>DD</sub> < 2.7 V					μs
TI50, TI51 input	<b>f</b> T15	V <sub>DD</sub> = 2.7 to 5.5 V	V <sub>DD</sub> = 2.7 to 5.5 V				4	MHz
frequency		V <sub>DD</sub> = 1.8 to 5.5 V			0		275	kHz
TI50, TI51 input ttih5, ttil5		V <sub>DD</sub> = 2.7 to 5.5 V			100			ns
high-/low-level width		V <sub>DD</sub> = 1.8 to 5.5 V						μs
Interrupt request	input high-/low-		0 to P47 V <sub>DD</sub> = 2.7	V <sub>DD</sub> = 2.7 to 5.5 V	1			μs
level width				V <sub>DD</sub> = 1.8 to 5.5 V	2			μs
RESET	trsL	V <sub>DD</sub> = 2.7 to 5.5 V		10			μs	
low-level width		V <sub>DD</sub> = 1.8 to 5.5 V		20			μs	

**Notes 1.** Value when using an external clock. When using a crystal resonator, the value becomes 114  $\mu$ s (MIN.).

2. Selection of  $f_{sam} = f_x$ ,  $f_x/4$ ,  $f_x/64$  is possible using bits 0 and 1 (PRM00, PRM01) of prescaler mode register 0 (PRM0). However, if the TI00 valid edge is selected as the count clock, the value becomes  $f_{sam} = f_x/8$ .

www.DataSheet4U.com

# Tcy vs. VDD (main system clock)



# (2) Read/write operation ( $T_A = -40 \text{ to } +85^{\circ}\text{C}$ , $V_{DD} = 4.0 \text{ to } 5.5 \text{ V}$ )

(1/3)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
ASTB high-level width	tasth		0.3tcy		ns
Address setup time	tads		20		ns
Address hold time	tadh		6		ns
Input time from address to data	tadd1			(2 + 2n)tcy - 54	ns
	t <sub>ADD2</sub>			(3 + 2n)tcy - 60	ns
Output time from RD↓ to address	trdad		0	100	ns
Input time from RD↓ to data	t <sub>RDD1</sub>			(2 + 2n)tcy - 87	ns
	t <sub>RDD2</sub>			(3 + 2n)tcy - 93	ns
Read data hold time	tпрн		0		ns
RD low-level width	tRDL1		(1.5 + 2n)tcy - 33		ns
	tRDL2		(2.5 + 2n)tcy - 33		ns
Input time from RD↓ to WAIT↓	trdwT1			tcy - 43	ns
	trdwt2			tcy - 43	ns
Input time from WR↓ to WAIT↓	twrwt			tcy - 25	ns
WAIT low-level width	tw⊤∟		(0.5 + n)tcy + 10	(2 + 2n)tcy	ns
Write data setup time	twos		60		ns
Write data hold time	twdн		6		ns
WR low-level width	twrL1		(1.5 + 2n)tcy - 15		ns
Delay time from ASTB↓ to RD↓	tastrd		6		ns
Delay time from ASTB↓ to WR↓	tastwr		2tcy - 15		ns
Delay time from RD↑ to ASTB↑ in external fetch	trdast		0.8tcy - 15	1.2tcy	ns
Hold time from RD↑ to address in external fetch	trdadh		0.8tcy - 15	1.2tcy + 30	ns
Write data output time from RD↑	trowo		40		ns
Write data output time from WR↓	twrwd		10	60	ns
Hold time from WR↑ to address	twradh		0.8tcy - 15	1.2tcy + 30	ns
Delay time from WAIT↑ to RD↑	twrd		0.8tcy	2.5tcy + 25	ns
Delay time from WAIT↑ to WR↑	twrwn		0.8tcy	2.5tcy + 25	ns

**Remarks 1.** tcy = Tcy/4

- 2. n indicates the number of waits.
- 3.  $C_L = 100 \text{ pF}$  ( $C_L$  is the load capacitance of the AD0 to AD7, A8 to A15,  $\overline{RD}$ ,  $\overline{WR}$ ,  $\overline{WAIT}$ , and ASTB pins.)

# (2) Read/write operation ( $T_A = -40 \text{ to } +85^{\circ}\text{C}$ , $V_{DD} = 2.7 \text{ to } 4.0 \text{ V}$ )

(2/3)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
ASTB high-level width	<b>t</b> asth		0.3tcy		ns
Address setup time	tads		30		ns
Address hold time	tadh		10		ns
Input time from address to data	tADD1			(2 + 2n)tcy - 108	ns
	tADD2			(3 + 2n)tcy - 120	ns
Output time from RD↓ to address	trdad		0	200	ns
Input time from RD↓ to data	tRDD1			(2 + 2n)tcy - 148	ns
	tRDD2			(3 + 2n)tcy - 162	ns
Read data hold time	<b>t</b> RDH		0		ns
RD low-level width	t <sub>RDL1</sub>		(1.5 + 2n)tcy - 40		ns
	tRDL2		(2.5 + 2n)toy - 40		ns
Input time from RD↓ to WAIT↓	trdwt1			tcy - 75	ns
	trdwt2			tcy - 60	ns
Input time from $\overline{\mathrm{WR}}\!\downarrow$ to $\overline{\mathrm{WAIT}}\!\downarrow$	twrwt			tcy - 50	ns
WAIT low-level width	twTL		(0.5 + 2n)tcy + 10	(2 + 2n)tcy	ns
Write data setup time	twos		60		ns
Write data hold time	twdн		10		ns
WR low-level width	twrL1		(1.5 + 2n)tcy - 30		ns
Delay time from ASTB↓ to $\overline{RD}$ ↓	tastrd		10		ns
Delay time from ASTB↓ to WR↓	tastwr		2tcy - 30		ns
Delay time from RD↑ to ASTB↑ in external fetch	trdast		0.8tcy - 30	1.2tcy	ns
Hold time from RD↑ to address in external fetch	trdadh		0.8tcy - 30	1.2tcy + 60	ns
Write data output time from RD↑	trowd		40		ns
Write data output time from WR↓	twrwd		20	120	ns
Hold time from WR↑ to address	twradh		0.8tcy - 30	1.2tcy + 60	ns
Delay time from WAIT↑ to RD↑	twrnd		0.5tcy	2.5tcy + 50	ns
Delay time from WAIT↑ to WR↑	twrwr		0.5tcy	2.5tcy + 50	ns

## **Remarks 1.** tcy = Tcy/4

- 2. n indicates the number of waits.
- 3.  $C_L = 100 \text{ pF}$  ( $C_L$  is the load capacitance of the AD0 to AD7, A8 to A15,  $\overline{RD}$ ,  $\overline{WR}$ ,  $\overline{WAIT}$ , and ASTB pins.)

# (2) Read/write operation ( $T_A = -40 \text{ to } +85^{\circ}\text{C}$ , $V_{DD} = 1.8 \text{ to } 2.7 \text{ V}$ )

(3/3)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
ASTB high-level width	tasth		0.3tcy		ns
Address setup time	tads		120		ns
Address hold time	tadh		20		ns
Input time from address to data	t <sub>ADD1</sub>			(2 + 2n)tcy - 233	ns
	t <sub>ADD2</sub>			(3 + 2n)tcy - 240	ns
Output time from RD↓ to address	trdad		0	400	ns
Input time from RD↓ to data	t <sub>RDD1</sub>			(2 + 2n)tcy - 325	ns
	tRDD2			(3 + 2n)tcy - 332	ns
Read data hold time	<b>t</b> RDH		0		ns
RD low-level width	tRDL1		(1.5 + 2n)tcy - 92		ns
	tRDL2		(2.5 + 2n)tcy - 92		ns
Input time from RD↓ to WAIT↓	tnDWT1			tcy - 350	ns
	tRDWT2			tcy - 132	ns
Input time from WR↓ to WAIT↓	twrwt			tcy - 100	ns
WAIT low-level width	twTL		(0.5 + 2n)tcy + 10	(2 + 2n)tcy	ns
Write data setup time	twos		60		ns
Write data hold time	twoн		20		ns
WR low-level width	twrL1		(1.5 + 2n)tcy - 60		ns
Delay time from ASTB↓ to $\overline{RD} \downarrow$	tastrd		20		ns
Delay time from ASTB $\downarrow$ to $\overline{\text{WR}} \downarrow$	tastwr		2tcy - 60		ns
Delay time from RD↑ to ASTB↑ in external fetch	trdast		0.8tcy - 60	1.2tcy	ns
Hold time from RD↑ to address in external fetch	trdadh		0.8tcy - 60	1.2tcy + 120	ns
Write data output time from RD↑	trowd		40		ns
Write data output time from WR↓	twrwd		40	240	ns
Hold time from WR↑ to address	twradh		0.8tcy - 60	1.2tcy + 120	ns
Delay time from WAIT↑ to RD↑	twrnd		0.5tcy	2.5tcy + 100	ns
Delay time from WAIT↑ to WR↑	twrwr		0.5tcy	2.5tcy + 100	ns

**Remarks 1.** tcy = Tcy/4

- 2. n indicates the number of waits.
- 3.  $C_L = 100 \text{ pF}$  ( $C_L$  is the load capacitance of the AD0 to AD7, A8 to A15,  $\overline{RD}$ ,  $\overline{WR}$ ,  $\overline{WAIT}$ , and ASTB pins.)

## (3) Serial interface ( $T_A = -40 \text{ to } +85^{\circ}\text{C}$ , $V_{DD} = 1.8 \text{ to } 5.5 \text{ V}$ )

# (a) 3-wire serial I/O mode (SCK3n... internal clock output)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
SCK3n cycle time	tkcy1	$4.0 \text{ V} \leq \text{V}_{DD} \leq 5.5 \text{ V}$	954			ns
		2.7 V ≤ V <sub>DD</sub> < 4.0 V	1,600			ns
		1.8 V ≤ V <sub>DD</sub> < 2.7 V	3,200			ns
SCK3n high-/low-level	t <sub>KH1</sub>	V <sub>DD</sub> = 4.0 to 5.5 V	tkcy1/2 - 50			ns
width	t <sub>KL1</sub>	V <sub>DD</sub> = 1.8 to 5.5 V	tkcy1/2 - 100			ns
SI3n setup time	tsıĸ1	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V	100			ns
(to SCK3n↑)		2.7 V ≤ V <sub>DD</sub> < 4.0 V	150			ns
		1.8 V ≤ V <sub>DD</sub> < 2.7 V	300			ns
SI3n hold time (from SCK3n↑)	tksıı		400			ns
Output delay time from SCK3n↓ to SO3n	tkso1	C = 100 pF <sup>Note</sup>			300	ns

**Note** C is the load capacitance of the  $\overline{SCK3n}$  and SO3n output lines.

# (b) 3-wire serial I/O mode (SCK3n... external clock input)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
SCK3n cycle time	tkcy2	$4.0~V \leq V_{DD} \leq 5.5~V$	800			ns
		$2.7 \text{ V} \leq \text{V}_{DD} < 4.0 \text{ V}$	1,600			ns
		1.8 V ≤ V <sub>DD</sub> < 2.7 V	3,200			ns
SCK3n high-/low-level	tкн2	$4.0~V \leq V_{DD} \leq 5.5~V$	400			ns
width	t <sub>KL2</sub>	$2.7 \text{ V} \leq \text{V}_{DD} < 4.0 \text{ V}$	800			ns
		$1.8~V \leq V_{DD} < 2.7~V$	1,600			ns
SI3n setup time (to SCK3n↑)	tsık2		100			ns
SI3n hold time (from SCK3n↑)	tksi2		400			ns
Output delay time from SCK3n↓ to SO3n	tkso2	C = 100 pF <sup>Note</sup>			300	ns

**Note** C is the load capacitance of the SO3n output line.

**Remark**  $\mu$ PD78F0034A: n = 0, 1  $\mu$ PD78F0034AY: n = 0

www.DataSheet4U.com 36 Data Sheet U14040EJ4V0DS

# (c) UART mode (dedicated baud rate generator output)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Transfer rate		$4.0~V \leq V_{\text{DD}} \leq 5.5~V$			131,031	bps
		$2.7 \text{ V} \leq \text{V}_{DD} < 4.0 \text{ V}$			78,125	bps
		1.8 V ≤ V <sub>DD</sub> < 2.7 V			39,063	bps

# (d) UART mode (external clock input)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
ASCK0 cycle time	tксүз	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V	800			ns
		2.7 V ≤ V <sub>DD</sub> < 4.0 V	1,600			ns
		1.8 V ≤ V <sub>DD</sub> < 2.7 V	3,200			ns
ASCK0 high-/low-level	<b>t</b> кнз,	4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V	400			ns
width	tкLз	2.7 V ≤ V <sub>DD</sub> < 4.0 V	800			ns
		1.8 V ≤ V <sub>DD</sub> < 2.7 V	1,600			ns
Transfer rate		4.0 V ≤ V <sub>DD</sub> ≤ 5.5 V			39,063	bps
		2.7 V ≤ V <sub>DD</sub> < 4.0 V			19,531	bps
		1.8 V ≤ V <sub>DD</sub> < 2.7 V			9,766	bps

# (e) UART mode (infrared data transfer mode)

Parameter	Symbol	Conditions	MIN.	MAX.	Unit
Transfer rate		V <sub>DD</sub> = 4.0 to 5.5 V		131,031	bps
Bit rate allowable error		V <sub>DD</sub> = 4.0 to 5.5 V		±0.87	%
Output pulse width		V <sub>DD</sub> = 4.0 to 5.5 V	1.2	0.24/fbr <sup>Note</sup>	μs
Input pulse width		V <sub>DD</sub> = 4.0 to 5.5 V	4/fx		μs

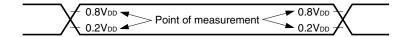
Note fbr: Specified baud rate

# (f) $I^2C$ bus Mode ( $\mu$ PD78F0034AY only)

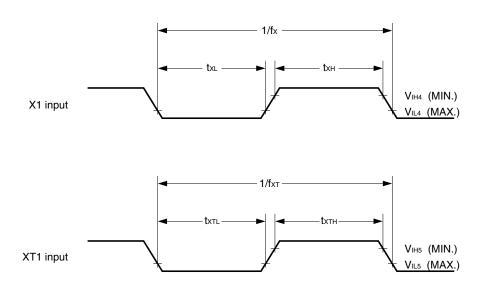
Parameter		Symbol	Standa	Standard Mode		High-Speed Mode		
			MIN.	MAX.	MIN.	MAX.		
SCL0 clock freq	uency	fclk	0	100	0	400	kHz	
Bus free time (between stop a	and start condition)	tbuf	4.7	_	1.3	_	μs	
Hold time <sup>Note 1</sup>		thd:STA	4.0	_	0.6	_	μs	
SCL0 clock low-	-level width	tLOW	4.7	_	1.3	_	μs	
SCL0 clock high	n-level width	tніgн	4.0	_	0.6	_	μs	
Start/restart cor	ndition setup time	tsu:sta	4.7	_	0.6	-	μs	
Data hold time	CBUS compatible master	thd:dat	5.0	_	-	-	μs	
	I <sup>2</sup> C bus		O <sup>Note 2</sup>	_	O <sup>Note 2</sup>	0.9 <sup>Note 3</sup>	μs	
Data setup time		tsu:dat	250	_	100 <sup>Note 4</sup>	-	ns	
SDA0 and SCL0 signal rise time		tR	-	1,000	20 + 0.1Cb <sup>Note 5</sup>	300	ns	
SDA0 and SCL0 signal fall time		t⊧	-	300	20 + 0.1Cb <sup>Note 5</sup>	300	ns	
Stop condition setup time		tsu:sто	4.0	_	0.6	-	μs	
Spike pulse width controlled by input filter		tsp	_	_	0	50	ns	
Capacitive load	per each bus line	Cb	_	400	_	400	pF	

- Notes 1. In the start condition, the first clock pulse is generated after this hold time.
  - 2. To fill in the undefined area of the SCL0 falling edge, it is necessary for the device to internally provide at least 300 ns of hold time for the SDA0 signal (which is VIHmin. of the SCL0 signal).
  - 3. If the device does not extend the SCL0 signal low hold time (tLow), only maximum data hold time thd:DAT needs to be fulfilled.
  - 4. The high-speed mode I<sup>2</sup>C bus is available in a standard mode I<sup>2</sup>C bus system. At this time, the conditions described below must be satisfied.
    - If the device does not extend the SCL0 signal low state hold time  $tsu:dat \ge 250 ns$
    - If the device extends the SCL0 signal low state hold time Be sure to transmit the next data bit to the SDA0 line before the SCL0 line is released (trans... + tsu:DAT = 1,000 + 250 = 1,250 ns by standard mode  $I^2C$  bus specification).
  - 5. Cb: Total capacitance per one bus line (unit: pF)

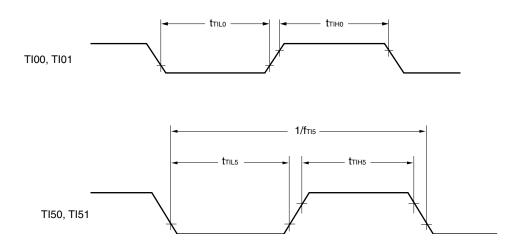
# AC Timing Measurement Point (Excluding X1, XT1 Input)



# **Clock Timing**

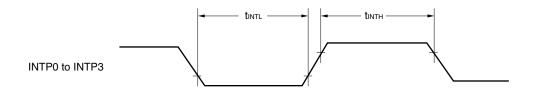


# **TI Timing**

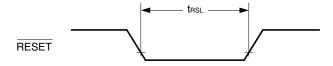




Interrupt Request Input Timing

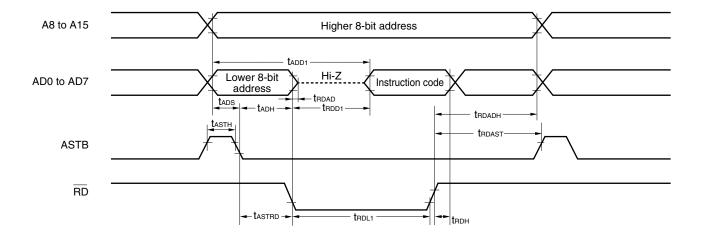


**RESET** Input Timing

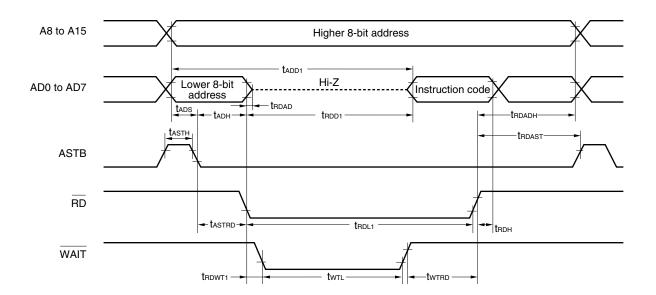


# External fetch (no wait):

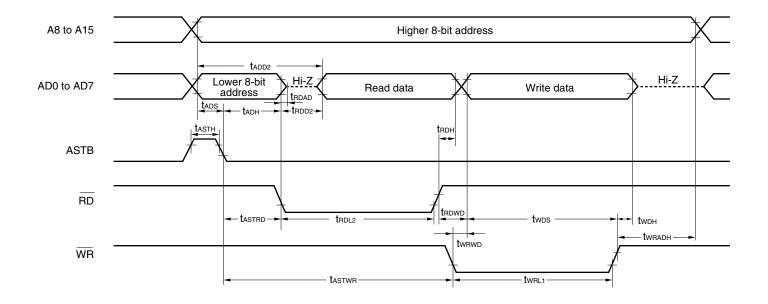
**Read/Write Operation** 



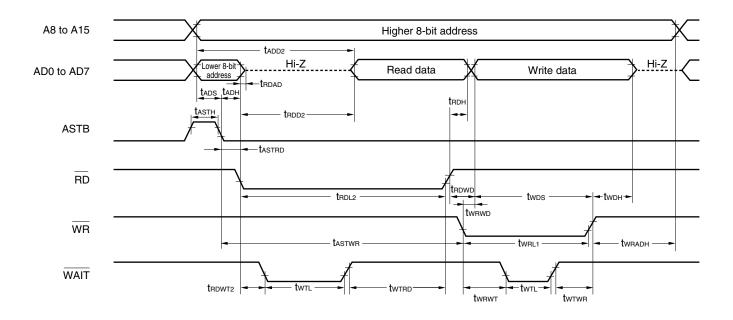
### External fetch (wait insertion):



#### External data access (no wait):



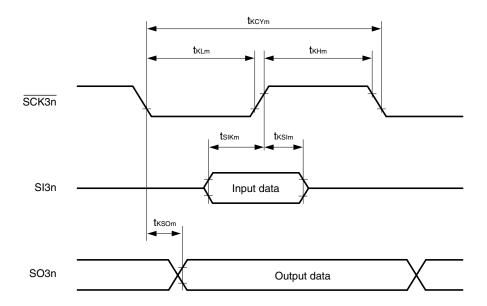
#### External data access (wait insertion):



#### www.DataSheet4U.com

### **Serial Transfer Timing**

#### 3-wire serial I/O mode:

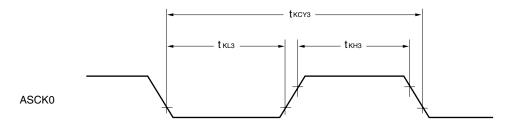


Remarks 1. m = 1, 2

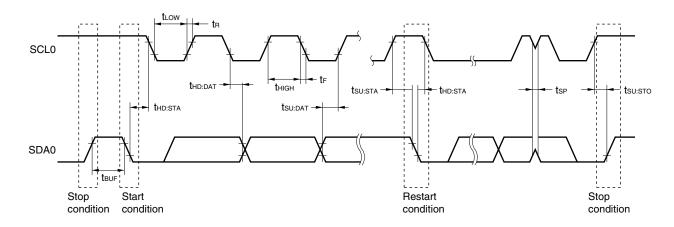
**2.**  $\mu$ PD78F0034A: n = 0, 1

**3.**  $\mu$ PD78F0034AY: n = 0

# **UART** mode (external clock input):



# $I^2C$ bus mode ( $\mu$ PD78F0034AY only):



## A/D Converter Characteristics (TA = -40 to +85°C, VDD = AVDD = AVREF = 1.8 to 5.5 V, AVSS = VSS = 0 V)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Resolution			10	10	10	bit
Overall error Note		$4.0 \text{ V} \leq \text{AV}_{\text{REF}} \leq 5.5 \text{ V}$		±0.2	±0.4	%FSR
		2.7 V ≤ AVREF < 4.0 V		±0.3	±0.6	%FSR
		1.8 V ≤ AV <sub>REF</sub> < 2.7 V		±0.6	±1.2	%FSR
Conversion time	tconv	$4.0 \text{ V} \leq \text{AV}_{\text{REF}} \leq 5.5 \text{ V}$	14		96	μs
		$2.7 \text{ V} \leq \text{AV}_{\text{REF}} < 4.0 \text{ V}$	19		96	μs
		1.8 V ≤ AV <sub>REF</sub> < 2.7 V	28		96	μs
Zero-scale errorNotes 1, 2		$4.0 \text{ V} \leq \text{AV}_{\text{REF}} \leq 5.5 \text{ V}$			±0.4	%FSR
		$2.7 \text{ V} \leq \text{AV}_{\text{REF}} < 4.0 \text{ V}$			±0.6	%FSR
		1.8 V ≤ AV <sub>REF</sub> < 2.7 V			±1.2	%FSR
Full-scale error Notes 1, 2		$4.0 \text{ V} \leq \text{AV}_{\text{REF}} \leq 5.5 \text{ V}$			±0.4	%FSR
		$2.7 \text{ V} \leq \text{AV}_{\text{REF}} < 4.0 \text{ V}$			±0.6	%FSR
		1.8 V ≤ AV <sub>REF</sub> < 2.7 V			±1.2	%FSR
Integral linearity error <sup>Note 1</sup>		$4.0 \text{ V} \leq \text{AV}_{\text{REF}} \leq 5.5 \text{ V}$			±2.5	LSB
		2.7 V ≤ AVREF < 4.0 V			±4.5	LSB
		1.8 V ≤ AV <sub>REF</sub> < 2.7 V			±8.5	LSB
Differential linearity error		4.0 V ≤ AVREF ≤ 5.5 V			±1.5	LSB
		2.7 V ≤ AV <sub>REF</sub> ≤ 4.0 V			±2.0	LSB
		1.8 V ≤ AVREF < 2.7 V			±3.5	LSB
Analog input voltage	VIAN		0		AVREF	V
Reference voltage	AVREF		1.8		AVDD	V
Resistance between AVREF and AVSS	RREF	During A/D conversion operation	20	40		kΩ

**Notes 1.** Excluding quantization error ( $\pm 1/2$  LSB).

2. Indicated as a ratio to the full-scale value (%FSR).

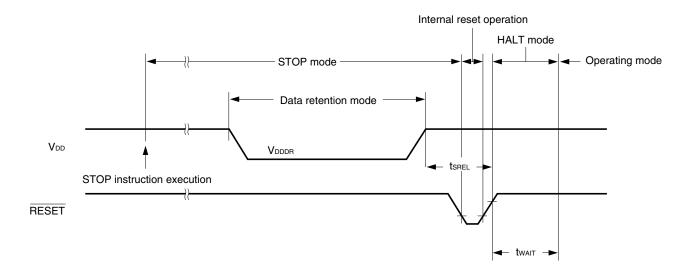
**Remark** When the  $\mu$ PD78F0034A or 78F0034AY is used as an 8-bit resolution A/D converter, the specifications are the same as for the  $\mu$ PD780024A or 78F0024AY Subseries A/D converter.

# Data Memory STOP Mode Low Supply Voltage Data Retention Characteristics (T<sub>A</sub> = -40 to +85°C)

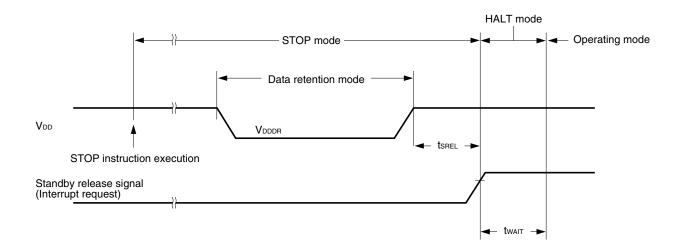
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Data retention supply voltage	VDDDR		1.6		5.5	V
Data retention supply current	IDDDR	Subsystem clock stop (XT1 = V <sub>DD</sub> ) and feed-back resistor disconnected		0.1	30	μА
Release signal set time	tsrel		0			μs
Oscillation stabilization wait time	twait	Release by RESET		2 <sup>17</sup> /fx		S
		Release by interrupt request		Note		S

**Note** Selection of  $2^{12}$ /fx and  $2^{14}$ /fx to  $2^{17}$ /fx is possible using bits 0 to 2 (OSTS0 to OSTS2) of the oscillation stabilization time select register (OSTS).

# Data Retention Timing (STOP Mode Release by RESET)



# Data Retention Timing (Standby Release Signal: STOP Mode Release by Interrupt Request Signal)



## Flash Memory Programming Characteristics (VDD = 2.7 to 5.5 V, Vss = 0 V, VPP = 9.7 to 10.3 V)

# (1) Basic characteristics

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Operating frequency	fx	$4.0 \le V_{DD} \le 5.5 V$	1.0		8.38	MHz
		2.7 ≤ V <sub>DD</sub> < 4.0 V	1.0		5.0	MHz
Supply voltage	V <sub>DD</sub>	Operation voltage when writing	2.7		5.5	V
	VPPL	Upon VPP low-level detection	0		0.2V <sub>DD</sub>	V
	V <sub>PP</sub>	Upon VPP high-level detection	0.8V <sub>DD</sub>	V <sub>DD</sub>	1.2V <sub>DD</sub>	V
	VPPH	Upon VPP high-voltage detection	9.7 <sup>Note 1</sup>	10.0 <sup>Note 1</sup>	10.3 <sup>Note 1</sup>	V
V <sub>DD</sub> supply current	IDD				10	mA
V <sub>PP</sub> supply current	IPP	V <sub>PP</sub> =10.0 V		75	100	mA
Write time (per byte)	Twrt		50		500	μs
Number of rewrites	Cwrt				20 <sup>Note 2</sup>	Times
Erase time	TERASE		1		20	s
Programming temperature	TPRG		+10		+40	°C

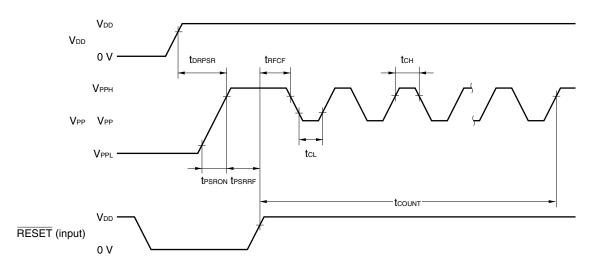
Notes 1. For the product grades "K, E, and P", 10.2 V (MIN.), 10.3 V (TYP.), and 10.4 V (MAX.), are applied.

2. For the product specification "K and E", the number is 1 (MAX.).

# (2) Serial write operation characteristics

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
V <sub>PP</sub> set time	tpsron	V <sub>PP</sub> high voltage	1.0			μs
Set time from V <sub>DD</sub> ↑ to V <sub>PP</sub> ↑	torpsr	V <sub>PP</sub> high voltage	1.0			μs
Set time from V <sub>PP</sub> ↑ to RESET↑	tpsrrf	V <sub>PP</sub> high voltage	1.0			μs
V <sub>PP</sub> count start time from RESET↑	trece		1.0			μs
Count execution time	tсоинт				2.0	ms
V <sub>PP</sub> counter high-level width	tсн		8.0			μs
V <sub>PP</sub> counter low-level width	tcL		8.0			μs
V <sub>PP</sub> counter noise elimination width	tnfw			40		ns

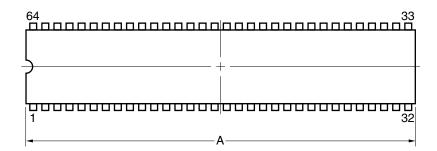
# Flash Memory Write Mode Set Timing

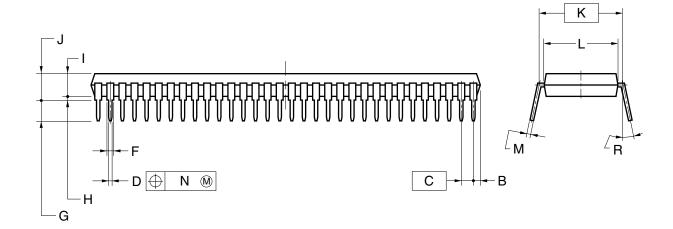


#### www.DataSneet4U.com

### 8. PACKAGE DRAWINGS

# 64-PIN PLASTIC SDIP (19.05mm(750))





#### **NOTES**

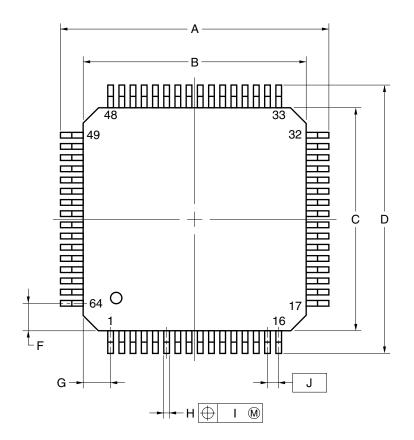
- Each lead centerline is located within 0.17 mm of its true position (T.P.) at maximum material condition.
- 2. Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS
Α	58.0 <sup>+0.68</sup> <sub>-0.20</sub>
В	1.78 MAX.
С	1.778 (T.P.)
D	0.50±0.10
F	0.9 MIN.
G	3.2±0.3
Н	0.51 MIN.
1	$4.05^{+0.26}_{-0.20}$
J	5.08 MAX.
K	19.05 (T.P.)
L	17.0±0.2
М	0.25+0.10
N	0.17
R	0 ~ 15°

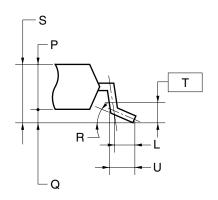
P64C-70-750A,C-4

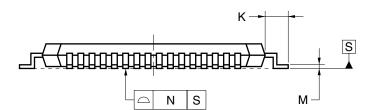
Remark The package and material of ES products are the same as mass produced products.

# 64-PIN PLASTIC LQFP (10x10)



detail of lead end





#### NOTE

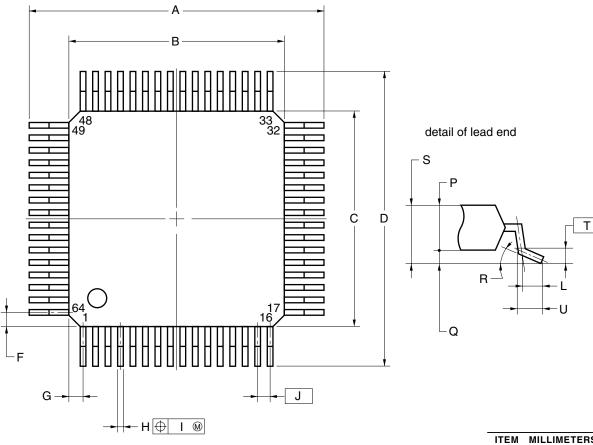
Each lead centerline is located within 0.08 mm of its true position (T.P.) at maximum material condition.

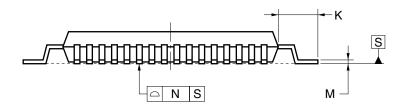
ITEM	MILLIMETERS
Α	12.0±0.2
В	10.0±0.2
С	10.0±0.2
D	12.0±0.2
F	1.25
G	1.25
Н	0.22±0.05
I	0.08
J	0.5 (T.P.)
K	1.0±0.2
L	0.5
М	$0.17^{+0.03}_{-0.07}$
N	0.08
Р	1.4
Q	0.1±0.05
R	3°+4°
S	1.5±0.10
Т	0.25
U	0.6±0.15
	S64GB-50-8FII-2

Remark The package and material of ES products are the same as mass produced products.

www.DataSheet4U.com

# **★** 64-PIN PLASTIC LQFP (14x14)





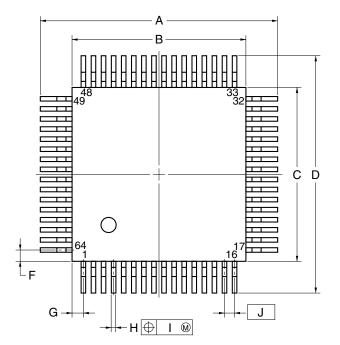
#### NOTE

Each lead centerline is located within 0.20 mm of its true position (T.P.) at maximum material condition.

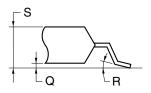
ITEM	MILLIMETERS
Α	17.2±0.2
В	14.0±0.2
С	14.0±0.2
D	17.2±0.2
F	1.0
G	1.0
Н	$0.37^{+0.08}_{-0.07}$
- 1	0.20
J	0.8 (T.P.)
K	1.6±0.2
L	0.8
М	$0.17^{+0.03}_{-0.06}$
N	0.10
Р	1.4±0.1
Q	0.127±0.075
R	3° +4° -3°
S	1.7 MAX.
Т	0.25
U	0.886±0.15
	P64GC-80-8BS

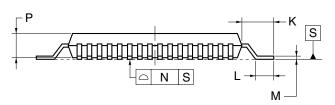
**Remark** The package and material of ES products are the same as mass produced products.

# 64-PIN PLASTIC QFP (14x14)



detail of lead end





### NOTE

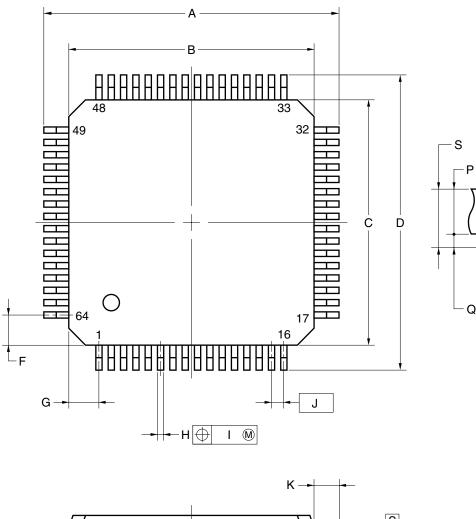
Each lead centerline is located within 0.15 mm of its true position (T.P.) at maximum material condition.

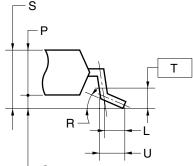
ITEM	MILLIMETERS
Α	17.6±0.4
В	14.0±0.2
С	14.0±0.2
D	17.6±0.4
F	1.0
G	1.0
Н	$0.37^{+0.08}_{-0.07}$
I	0.15
J	0.8 (T.P.)
K	1.8±0.2
L	0.8±0.2
М	$0.17^{+0.08}_{-0.07}$
N	0.10
Р	2.55±0.1
Q	0.1±0.1
R	5°±5°
S	2.85 MAX.
	P64GC-80-AB8-5

**Remark** The package and material of ES products are the same as mass produced products.

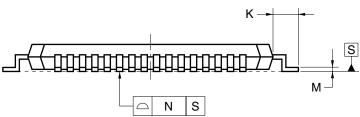
www.DataSheet4U.com

# 64-PIN PLASTIC TQFP (12x12)





detail of lead end



### NOTE

Each lead centerline is located within 0.13 mm of its true position (T.P.) at maximum material condition.

ITEM	MILLIMETERS	
Α	14.0±0.2	
В	12.0±0.2	
С	12.0±0.2	
D	14.0±0.2	
F	1.125	
G	1.125	
Н	$0.32^{+0.06}_{-0.10}$	
ı	0.13	
J	0.65 (T.P.)	
K	1.0±0.2	
L	0.5	
М	$0.17^{+0.03}_{-0.07}$	
N	0.10	
Р	1.0	
Q	0.1±0.05	
R	3°+4°	
S	1.1±0.1	
Т	0.25	
U	0.6±0.15	
	P64GK-65-9ET-3	

**Remark** The package and material of ES products are the same as mass produced products.

#### **★** 9. RECOMMENDED SOLDERING CONDITIONS

The  $\mu$ PD78F0034A, 78F0034AY should be soldered and mounted under the following recommended conditions. For details of the recommended soldering conditions, refer to the document **Semiconductor Device Mounting Technology Manual (C10535E)**.

For soldering methods and conditions other than those recommended below, contact your NEC sales representative.

Table 9-1. Surface Mounting Type Soldering Conditions (1/2)

(1)  $\mu$ PD78F0034AGC-8BS: 64-pin plastic LQFP (14 × 14)  $\mu$ PD78F0034AYGC-8BS: 64-pin plastic LQFP (14 × 14)  $\mu$ PD78F0034AGC-AB8: 64-pin plastic QFP (14 × 14)  $\mu$ PD78F0034AYGC-AB8: 64-pin plastic QFP (14 × 14)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 235°C, Time: 30 seconds max. (at 210°C or higher), Count: Two times or less	IR35-00-2
VPS	Package peak temperature: 215°C, Time: 40 seconds max. (at 200°C or higher), Count: Two times or less	VP15-00-2
Wave soldering	Solder bath temperature: 260°C max., Time: 10 seconds max., Count: Once, Preheating temperature: 120°C max. (package surface temperature)	WS60-00-1
Partial heating	Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)	-

Caution Do not use different soldering methods together (except for partial heating).

(2)  $\mu$ PD78F0034AGB-8EU: 64-pin plastic LQFP (10 × 10)  $\mu$ PD78F0034AYGB-8EU: 64-pin plastic LQFP (10 × 10)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 235°C, Time: 30 seconds max. (at 210°C or higher), Count: Two times or less, Exposure limit: 7 days <sup>Note</sup> (after 7 days, prebake at 125°C for 10 hours)	IR35-107-2
VPS	Package peak temperature: 215°C, Time: 40 seconds max. (at 200°C or higher), Count: Two times or less, Exposure limit: 7 days <sup>Note</sup> (after 7 days, prebake at 125°C for 10 hours)	VP15-107-2
Partial heating	Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)	-

Note After opening the dry pack, store it at 25°C or less and 65% RH or less for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

www.DataSheet4U.com

Table 9-1. Surface Mounting Type Soldering Conditions (2/2)

(3)  $\mu$ PD78F0034AGK-9ET: 64-pin plastic TQFP (12 × 12)  $\mu$ PD78F0034AYGK-9ET: 64-pin plastic TQFP (12 × 12)

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared reflow	Package peak temperature: 235°C, Time: 30 seconds max. (at 210°C or higher), Count: Two times or less, Exposure limit: 7 days <sup>Note</sup> (after 7 days, prebake at 125°C for 10 hours)	IR35-107-2
VPS	Package peak temperature: 215°C, Time: 40 seconds max. (at 200°C or higher), Count: Two times or less, Exposure limit: 7 days <sup>Note</sup> (after 7 days, prebake at 125°C for 10 hours)	VP15-107-2
Wave soldering	Solder bath temperature: 260°C max., Time: 10 seconds max., Count: Once, Preheating temperature: 120°C max. (package surface temperature), Exposure limit: 7 days <sup>Note</sup> (after 7 days, prebake at 125°C for 10 hours)	WS60-107-1
Partial heating	Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)	-

**Note** After opening the dry pack, store it at 25°C or less and 65% RH or less for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

**Table 9-2. Insertion Type Soldering Conditions** 

 $\mu\text{PD78F0034ACW: 64-pin plastic SDIP (19.05 mm (750))}$   $\mu\text{PD78F0034AYCW: 64-pin plastic SDIP (19.05 mm (750))}$ 

Soldering M	ethod	Soldering Conditions
Wave soldering	(pin only)	Solder bath temperature: 260°C max., Time: 10 seconds max.
Partial heating		Pin temperature: 300°C max., Time: 3 seconds max. (per pin row)

Caution Apply wave soldering only to the pins and be careful not to bring solder into direct contact with the package.

# APPENDIX A. DEVELOPMENT TOOLS

The following development tools are available for system development using the  $\mu$ PD78F0034A, 78F0034AY Subseries.

Also refer to (5) Cautions on Using Development Tools.

### (1) Language Processing Software

RA78K0	Assembler package common to 78K/0 Series	
CC78K0	C compiler package common to 78K/0 Series	
DF780034	Device file for μPD780034A, 78F0034AY Subseries	
CC78K0-L	C compiler library source file common to 78K/0 Series	

# (2) Flash Memory Writing Tools

Flashpro III (part No. FL-PR3, PG-FP3)	Flash programmer dedicated to microcontrollers with on-chip flash memory	
(part No. 1 E-1 115, 1 G-1 1 5)		
FA-64CW, FA-64GC,	Adapter for flash memory writing	
FA-64GC-8BS,		
FA-64GB-8EU,		
FA-64GK-9ET		

# (3) Debugging Tools

#### • When IE-78K0-NS in-circuit emulator is used

IE-78K0-NS	In-circuit emulator common to 78K/0 Series	
IE-70000-MC-PS-B	Power supply unit for IE-78K0-NS	
IE-78K0-NS-PA	Performance board that enhances and expands the IE-78K0-NS functions	
IE-70000-98-IF-C	Adapter required when using PC-9800 series PC (except notebook type) as host machine (C bus supported)	
IE-70000-CD-IF-A	PC card and interface cable when using PC-9800 series notebook PC as host machine (PCMCIA socket supported)	
IE-70000-PC-IF-C	Adapter required when using IBM PC/AT <sup>TM</sup> or compatible as host machine (ISA bus supported)	
IE-70000-PCI-IF-A	Adapter necessary when using PC in which PCI bus is incorporated as host machine	
IE-780034-NS-EM1	Emulation board to emulate the $\mu$ PD780034A, 78F0034AY Subseries	
NP-64CW	Emulation probe for 64-pin plastic SDIP (CW type)	
NP-64GC, NP-64GC-TQ	Emulation probe for 64-pin plastic QFP (CG-AB8, GC-8BS type)	
NP-64GK	Emulation probe for 64-pin plastic TQFP (GK-9ET type)	
NP-H64GB-TQ	Emulation probe for 64-pin plastic LQFP (GB-8EU type)	
EV-9200GC-64	Conversion socket to connect the NP-64GC and a target system board on which a 64-pin plastic QFP (GC-AB8, GC-8BS type) can be mounted	
TGC-064SAP	Conversion adapter to connect the NP-64GC-TQ and a target system board on which a 64-pin plastic QFP (GC-AB8, GC-8BS type) can be mounted	
TGK-064SBP	Conversion adapter to connect the NP-64GK and a target system board on which a 64-pin plasti TQFP (GK-9ET type) can be mounted	
TGB-064SDP	Conversion adapter to connect the NP-H64GB-TQ and a target system board on which a 64-pin plastic LQFP (GB-8EU type) can be mounted	
ID78K0-NS	Integrated debugger for IE-78K0-NS	
SM78K0	System simulator common to 78K/0 Series	
DF780034	Device file for μPD780034A, 78F0034AY Subseries	

# • When using in-circuit emulator IE-78001-R-A

IE-78001-R-A	In-circuit emulator common to 78K/0 Series	
IE-70000-98-IF-C	Adapter required when using PC-9800 series as host machine (excluding notebook PCs) (C bus supported)	
IE-70000-PC-IF-C	Adapter required when using IBM PC/AT or compatible as host machine (ISA bus supported)	
IE-70000-PCI-IF-A	Adapter required when using PC in which PCI bus is incorporated as host machine	
IE-780034-NS-EM1	Emulation board to emulate μPD780034A, 78F0034AY Subseries	
IE-78K0-R-EX1	Emulation probe conversion board to use IE-780034-NS-EM1 on IE-78001-R-A	
EP-78240CW-R	Emulation probe for 64-pin plastic SDIP (CW type)	
EP-78240GC-R	Emulation probe for 64-pin plastic QFP (GC-AB8, GC-8BS type)	
EP-78012GK-R	Emulation probe for 64-pin plastic TQFP (GK-9ET type)	
EV-9200GC-64	Conversion socket to connect the EP-78240GC-R and a target system board on which a 64-pin plastic QFP (GC-AB8, GC-8BS type) can be mounted	
TGK-064SBP	Conversion adapter to connect the EP-78012GK-R and a target system board on which a 64-pin plastic TQFP (GK-9ET type) can be mounted	
ID78K0	Integrated debugger for IE-78001-R-A	
SM78K0	System simulator common to 78K/0 Series	
DF780034	Device file for μPD780034A, 78F0034AY Subseries	

# (4) Real-Time OS

RX78K0	Real-time OS for 78K/0 Series
1 13 13 01 10	11001 11110 00 101 70140 001100

www DataSheet4U com

#### (5) Cautions on Using Development Tools

- The ID-78K0-NS, ID78K0, and SM78K0 are used in combination with the DF780034.
- The CC78K0 and RX78K0 are used in combination with the RA78K0 and the DF780034.
- The FL-PR3, FA-64CW, FA-64GC, FA-64GC-8BS, FA-64GB-8EU, FA-64GK-9ET, NP-64CW, NP-64GC, NP-64GC-TQ, NP-64GK, and NP-H64GB-TQ are products made by Naito Densei Machida Mfg. Co., Ltd. (+81-45-475-4191).
- The TGK-064SBW, TGC-064SAP, TGK-064-SBP, and TGB-064SDP are products made by TOKYO ELETECH CORPORATION.

For further information contact Daimaru Kogyo, Ltd.

Tokyo Electronic Division (+81-3-3820-7112)

Osaka Electronic Division (+81-6-6244-6672)

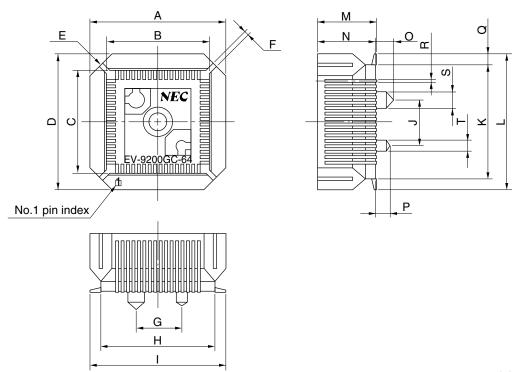
- For third party development tools, see the Single-Chip Microcontroller Selection Guide (U11069E).
- The host machines and OSs supporting each software are as follows.

Host Machine	PC	EWS
[OS]	PC-9800 series [Japanese Windows <sup>TM</sup> ] IBM PC/AT or compatibles	HP9000 series 700 <sup>TM</sup> [HP-UX <sup>TM</sup> ] SPARCstation <sup>TM</sup> [SunOS <sup>TM</sup> , Solaris <sup>TM</sup> ]
Software	[Japanese/English Windows]	
RA78K0	$\sqrt{Note}$	√
CC78K0	$\sqrt{Note}$	√
ID78K0-NS	$\checkmark$	-
ID78K0	$\checkmark$	-
SM78K0	$\checkmark$	_
RX78K0	$\sqrt{Note}$	V

Note DOS-based software

# Conversion Socket Drawing (EV-9200GC-64) and Footprints

Figure A-1. EV-9200GC-64 Drawing (For Reference Only)

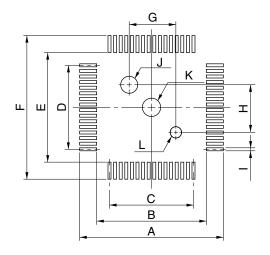


EV-9200GC-64-G0

ITEM	MILLIMETERS	INCHES
Α	18.8	0.74
В	14.1	0.555
С	14.1	0.555
D	18.8	0.74
Е	4-C 3.0	4-C 0.118
F	0.8	0.031
G	6.0	0.236
Н	15.8	0.622
I	18.5	0.728
J	6.0	0.236
K	15.8	0.622
L	18.5	0.728
М	8.0	0.315
N	7.8	0.307
0	2.5	0.098
Р	2.0	0.079
Q	1.35	0.053
R	0.35±0.1	$0.014^{+0.004}_{-0.005}$
S	φ2.3	φ0.091
Т	ø1.5	φ0.059



Figure A-2. EV-9200GC-64 Footprints (For Reference Only)



#### EV-9200GC-64-P1E

	21 020000 0111		
ITEM	MILLIMETERS	INCHES	
Α	19.5	0.768	
В	14.8	0.583	
С	0.8±0.02 × 15=12.0±0.05	$0.031^{+0.002}_{-0.001} \times 0.591 = 0.472^{+0.003}_{-0.002}$	
D	0.8±0.02 × 15=12.0±0.05	$0.031^{+0.002}_{-0.001} \times 0.591 = 0.472^{+0.003}_{-0.002}$	
Е	14.8	0.583	
F	19.5	0.768	
G	6.00±0.08	$0.236^{+0.004}_{-0.003}$	
Н	6.00±0.08	$0.236^{+0.004}_{-0.003}$	
I	0.5±0.02	$0.197^{+0.001}_{-0.002}$	
J	φ2.36±0.03	$\phi_{0.093^{+0.001}_{-0.002}}$	
K	φ2.2±0.1	$\phi$ 0.087 $^{+0.004}_{-0.005}$	
L	φ1.57±0.03	$\phi_{0.062^{+0.001}_{-0.002}}$	

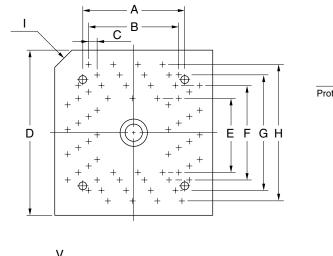
#### Caution

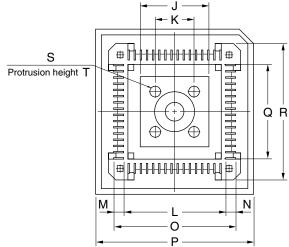
DimensionsofmountpadforEV-9200andthatfortargetdevice (QFP) may be different in some parts. For the recommended mountpaddimensionsforQFP, refer to "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (C10535E).

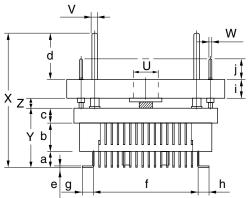
Data Sheet U14040EJ4V0DS www.DataSheet4U.com

# **Conversion Adapter Drawing (TGC-064SAP)**

Figure A-3. TGC-064SAP Drawing (For Reference Only)







ITEM	MILLIMETERS	INCHES	ITEM	MILLIMETERS
Α	14.12	0.556	а	1.85
В	0.8x15=12.0	0.031x0.591=0.472	b	3.5
С	0.8	0.031	С	2.0
D	20.65	0.813	d	6.0
Е	10.0	0.394	е	0.25
F	12.4	0.488	f	13.6
G	14.8	0.583	g	1.2
Н	17.2	0.677	h	1.2
1	C 2.0	C 0.079	i	2.4
J	9.05	0.356	j	2.7
K	5.0	0.197		T
L	13.35	0.526		
М	1.325	0.052		
N	1.325	0.052		
0	16.0	0.630		
Р	20.65	0.813		
Q	12.5	0.492		
R	17.5	0.689		
S	$4-\phi 1.3$	$4-\phi 0.051$		
Т	1.8	0.071		
U	$\phi$ 3.55	φ0.140		
V	φ0.9	φ0.035		
W	φ0.3	φ0.012		
X	(19.65)	(0.667)		

0.289

0.047

2.0 0.079 6.0 0.236 .25 0.010 13.6 0.535 1.2 0.047 2.4 0.047 0.094 0.106

TGC-064SAP-G0E

INCHES

0.073

0.138

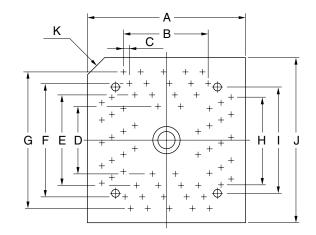
note: Product by TOKYO ELETECH CORPORATION.

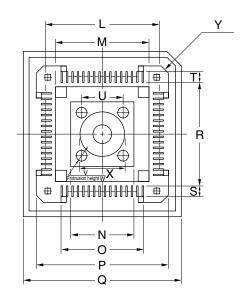
7.35

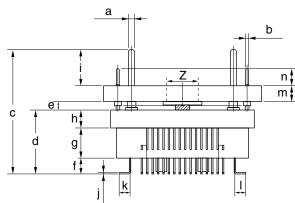
1.2

# **Conversion Adapter Drawing (TGK-064SBP)**

Figure A-4. TGK-064SBP Drawing (For Reference Only) (Unit: mm)







ITEM	MILLIMETERS	INCHES
A	18.4	0.724
В	0.65x15=9.75	0.026x0.591=0.384
С	0.65	0.026
D	7.75	0.305
Е	10.15	0.400
F	12.55	0.494
G	14.95	0.589
Н	0.65x15=9.75	0.026x0.591=0.384
I	11.85	0.467
J	18.4	0.724
K	C 2.0	C 0.079
L	12.45	0.490
М	10.25	0.404
N	7.7	0.303
0	10.02	0.394
P	14.92	0.587
Q	18.4	0.724
R	11.1	0.437
S	1.45	0.057
Т	1.45	0.057
U	5.0	0.197
V	4- <i>ϕ</i> 1.3	φ0.051
W	1.8	0.071
X	φ5.3	φ0.209
Y	4-C 1.0	4-C 0.039
Z	φ3.55	φ0.140

	ITEM	MILLIMETERS	INCHES
	а	φ0.9	$\phi$ 0.035
1	b	$\phi$ 0.3	$\phi$ 0.012
	С	(16.95)	(0.667)
	d	7.35	0.289
	е	1.2	0.047
_	f	1.85	0.073
	g	3.5	0.138
1	h	2.0	0.079
_	i	6.0	0.236
	j	0.25	0.010
	k	1.325	0.052
	I	1.325	0.052
	m	2.4	0.094
	n	2.7	0.106
_			

TGK-064SBP-G0E

**Note**: Product by TOKYO ELETECH CORPORATION.

#### APPENDIX B. RELATED DOCUMENTS

The related documents indicated in this publication may include preliminary versions. However, preliminary versions are not marked as such.

#### **Documents Related to Devices**

Document Name	Document No.
μPD780024A, 780034A, 780024AY, 780034AY Subseries User's Manual	U14046E
μPD780021A, 780022A, 780023A, 780024A, 780021AY, 780022AY, 780023AY, 780024AY Data Sheet	U14042E
μPD780021A(A), 780022A(A), 780023A(A), 780024A(A), 780021AY(A), 780022AY(A), 780023AY(A),	U15131E
780024AY(A) Data Sheet	
μPD780031A, 780032A, 780033A, 780034A, 780031AY, 780032AY, 780033AY, 780034AY Data Sheet	U14044E
μPD780031A(A), 780032A(A), 780033A(A), 780034A(A), 780031AY(A), 780032AY(A), 780033AY(A),	U15132E
780034AY(A) Data Sheet	
μPD78F0034A, 78F0034AY Data Sheet	This manual
78K/0 Series User's Manual Instruction	U12326E

# **★** Documents Related to Development Software Tools (User's Manuals)

Document Name	Document No.	
RA78K0 Assembler Package	Operation	U14445E
	Language	U14446E
	Structured Assembly Language	U11789E
CC78K0 C Compiler	Operation	U14297E
	Language	U14298E
SM78K0S, SM78K0 System Simulator Ver. 2.10 or Later	Operation (Windows Based)	U14611E
SM78K Series System Simulator Ver. 2.10 or Later	External Part User Open	U15006E
	Interface Specifications	
ID78K0-NS Integrated Debugger Ver. 2.00 or Later	Operation (Windows Based)	U14379E
ID78K0 Integrated Debugger Windows Based	Reference	U11539E
	Guide	U11649E
RX78K0 Real-Time OS	Fundamentals	U11537E
	Installation	U11536E
Project Manager Ver. 3.12 or Later (Windows Based)		U14610E

### **Documents Related to Development Hardware Tools (User's Manuals)**

Document Name	Document No.
IE-78K0-NS In-Circuit Emulator	U13731E
IE-78K0-NS-A In-Circuit Emulator	U14889E
IE-78001-R-A In-Circuit Emulator	U14142E
IE-78K0-R-EX1 In-Circuit Emulator	To be prepared

Caution The related documents listed above are subject to change without notice. Be sure to use the latest version of each document for designing.



www.DataSheet4LL.com

# **Documents Related to Flash Memory Writing**

Document Name	Document No.
PG-FP3 Flash Memory Programmer User's Manual	U13502E

### **Other Related Documents**

Document Name	Document No.
SEMICONDUCTORS SELECTION GUIDE - Products & Packages -	X13769E
Semiconductor Device Mounting Technology Manual	C10535E
Quality Grades on NEC Semiconductor Devices	C11531E
NEC Semiconductor Device Reliability/Quality Control System	C10983E
Guide to Prevent Damage for Semiconductor Devices by Electrostatic Discharge (ESD)	C11892E

Caution The related documents listed above are subject to change without notice. Be sure to use the latest version of each document for designing.

Data Sheet U14040EJ4V0DS www.DataSheet4U.com



www.DataSheet4U.com

[MEMO]



#### NOTES FOR CMOS DEVICES -

#### (1) PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note:

Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

#### (2) HANDLING OF UNUSED INPUT PINS FOR CMOS

Note:

No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS devices behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

#### (3) STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note:

Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

Note: Purchase of NEC I<sup>2</sup>C components conveys a license under the Philips I<sup>2</sup>C Patent Rights to use these components in an I<sup>2</sup>C system, provided that the system conforms to the I<sup>2</sup>C Standard Specification as defined by Philips.

FIP and IEBus are trademarks of NEC Corporation.

Windows is either a registered trademark or trademark of Microsoft Corporation in the United States and/or other countries.

PC/AT is a trademark of International Business Machines Corporation.

HP9000 series 700 and HP-UX are trademarks of Hewlett-Packard Company.

SPARCstation is a trademark of SPARC International, Inc.

Solaris and SunOS are trademarks of Sun Microsystems, Inc.

# **Regional Information**

Some information contained in this document may vary from country to country. Before using any NEC product in your application, please contact the NEC office in your country to obtain a list of authorized representatives and distributors. They will verify:

- · Device availability
- · Ordering information
- Product release schedule
- Availability of related technical literature
- Development environment specifications (for example, specifications for third-party tools and components, host computers, power plugs, AC supply voltages, and so forth)
- · Network requirements

In addition, trademarks, registered trademarks, export restrictions, and other legal issues may also vary from country to country.

# **NEC Electronics Inc. (U.S.)**

Santa Clara, California Tel: 408-588-6000 800-366-9782 Fax: 408-588-6130 800-729-9288

#### **NEC do Brasil S.A.**

Electron Devices Division Guarulhos-SP, Brasil Tel: 11-6462-6810 Fax: 11-6462-6829

#### **NEC Electronics (Europe) GmbH**

Duesseldorf, Germany Tel: 0211-65 03 01 Fax: 0211-65 03 327

• Branch The Netherlands Eindhoven, The Netherlands

Tel: 040-244 58 45 Fax: 040-244 45 80

• Branch Sweden Taeby, Sweden Tel: 08-63 80 820 Fax: 08-63 80 388

Filiale Italiana
Milano, Italy
Tel: 02-667541
Fax: 02-66754299

### **NEC Electronics (France) S.A.**

Vélizy-Villacoublay, France Tel: 01-3067-58-00 Fax: 01-3067-58-99

# NEC Electronics (France) S.A. Representación en España

Madrid, Spain Tel: 091-504-27-87 Fax: 091-504-28-60

#### NEC Electronics (UK) Ltd.

Milton Keynes, UK Tel: 01908-691-133 Fax: 01908-670-290

# **NEC Electronics Hong Kong Ltd.**

Hong Kong Tel: 2886-9318 Fax: 2886-9022/9044

#### **NEC Electronics Hong Kong Ltd.**

Seoul Branch Seoul, Korea Tel: 02-528-0303 Fax: 02-528-4411

# NEC Electronics Shanghai, Ltd.

Shanghai, P.R. China Tel: 021-6841-1138 Fax: 021-6841-1137

### **NEC Electronics Taiwan Ltd.**

Taipei, Taiwan Tel: 02-2719-2377 Fax: 02-2719-5951

# **NEC Electronics Singapore Pte. Ltd.**

Novena Square, Singapore

Tel: 253-8311 Fax: 250-3583

J02.3-1

- The information in this document is current as of February, 2002. The information is subject to change without notice. For actual design-in, refer to the latest publications of NEC's data sheets or data books, etc., for the most up-to-date specifications of NEC semiconductor products. Not all products and/or types are available in every country. Please check with an NEC sales representative for availability and additional information.
- No part of this document may be copied or reproduced in any form or by any means without prior written consent of NEC. NEC assumes no responsibility for any errors that may appear in this document.
- NEC does not assume any liability for infringement of patents, copyrights or other intellectual property rights of
  third parties by or arising from the use of NEC semiconductor products listed in this document or any other
  liability arising from the use of such products. No license, express, implied or otherwise, is granted under any
  patents, copyrights or other intellectual property rights of NEC or others.
- Descriptions of circuits, software and other related information in this document are provided for illustrative
  purposes in semiconductor product operation and application examples. The incorporation of these
  circuits, software and information in the design of customer's equipment shall be done under the full
  responsibility of customer. NEC assumes no responsibility for any losses incurred by customers or third
  parties arising from the use of these circuits, software and information.
- While NEC endeavours to enhance the quality, reliability and safety of NEC semiconductor products, customers
  agree and acknowledge that the possibility of defects thereof cannot be eliminated entirely. To minimize
  risks of damage to property or injury (including death) to persons arising from defects in NEC
  semiconductor products, customers must incorporate sufficient safety measures in their design, such as
  redundancy, fire-containment, and anti-failure features.
- NEC semiconductor products are classified into the following three quality grades:
  - "Standard", "Special" and "Specific". The "Specific" quality grade applies only to semiconductor products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of a semiconductor product depend on its quality grade, as indicated below. Customers must check the quality grade of each semiconductor product before using it in a particular application.
  - "Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
  - "Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
  - "Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC semiconductor products is "Standard" unless otherwise expressly specified in NEC's data sheets or data books, etc. If customers wish to use NEC semiconductor products in applications not intended by NEC, they must contact an NEC sales representative in advance to determine NEC's willingness to support a given application.

(Note)

- (1) "NEC" as used in this statement means NEC Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC semiconductor products" means any semiconductor product developed or manufactured by or for NEC (as defined above).